

## TPS2291xx Ultra-small, Low On Resistance Load Switch With Controlled Turn-on

### 1 Features

- Integrated Single Load Switch
- Four Pin Wafer-Chip-Scale Package (Nom)
  - 0.9 mm x 0.9 mm, 0.5-mm Pitch, 0.5-mm Height (YZV)
- Input Voltage Range: 1.4 V to 5.5 V
- Low ON-Resistance
  - $r_{ON} = 60 \text{ m}\Omega$  at  $V_{IN} = 5 \text{ V}$
  - $r_{ON} = 61 \text{ m}\Omega$  at  $V_{IN} = 3.3 \text{ V}$
  - $r_{ON} = 74 \text{ m}\Omega$  at  $V_{IN} = 1.8 \text{ V}$
  - $r_{ON} = 84 \text{ m}\Omega$  at  $V_{IN} = 1.5 \text{ V}$
- 2-A Maximum Continuous Switch Current
- Low Threshold Control Input
- Controlled Slew-rate
- Under-Voltage Lock Out
- Full-Time Reverse Current Protection
- Quick Output Discharge Transistor (TPS22913B/C Devices)

### 2 Applications

- Notebook Computer and Ultrabook™
- Tablets and Set-Top-Boxes
- Portable Industrial / Medical Equipment
- Portable Media Players
- Point Of Sale Pins
- GPS Navigation Devices
- Digital Cameras
- Portable Instrumentation
- Smartphones / Wireless Handsets

### 3 Description

The TPS22910A, TPS22912C, and TPS22913B/C are small, low  $r_{ON}$  load switches with controlled turn on. The device contains a P-channel MOSFET that can operate over an input voltage range of 1.4 V to 5.5 V. The switch is controlled by an on/off input (ON), which is capable of interfacing directly with low-voltage GPIO control signals.

The TPS22910A, TPS22912C, and TPS22913B/C devices provide reverse current protection in ON and OFF states. An internal reverse voltage comparator disables the power-switch when the output voltage ( $V_{OUT}$ ) is driven higher than the input voltage ( $V_{IN}$ ), by  $V_{RCP}$ , to quickly (10  $\mu\text{s}$  typ) stop the flow of current towards the input side of the switch. Reverse current protection is always active, even when the power-switch is disabled. Additionally, under-voltage lockout (UVLO) protection turns the switch off if the input voltage is too low.

The TPS22913B/C contains a 150- $\Omega$  on-chip load resistor for quick output discharge when the switch is turned off.

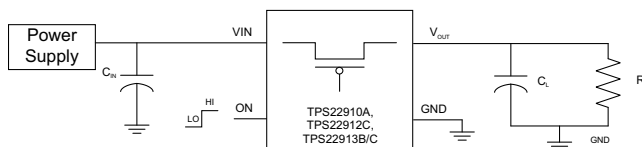
This family of devices have various slew rate options to avoid inrush current (see [Device Comparison Table](#) for details), are available in an ultra-small, space-saving 4-pin WCSP packages, and are characterized for operation over the free-air temperature range of  $-40^{\circ}\text{C}$  to  $85^{\circ}\text{C}$ .

#### Device Information<sup>(1)</sup>

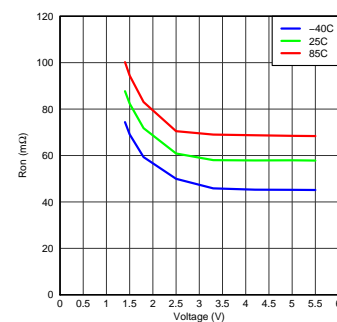
PART NUMBER	PACKAGE	BODY SIZE (NOM)
TPS22910A	DSBGA (4)	0.90 mm x 0.90 mm
TPS22912C		
TPS22913B		
TPS22913C		

(1) For all available packages, see the orderable addendum at the end of the datasheet.

### 4 Simplified Schematic



#### On-State Resistance vs Input Voltage



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## 5 Revision History

<b>Changes from Revision E (June 2014) to Revision F</b>	<b>Page</b>
• Updated 'ON' pin description in the Pin Functions table. ....	3

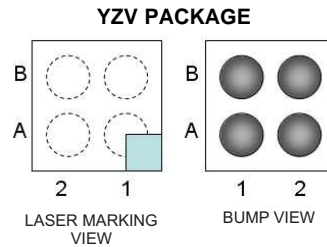
<b>Changes from Revision D (May 2014) to Revision E</b>	<b>Page</b>
• Updated Switching Characteristics table .....	6
• Updated Typical DC Characteristics section. ....	7
• Updated Timing Waveforms graphic. ....	17
• Updated Application Curves section. ....	22

<b>Changes from Revision C (May 2013) to Revision D</b>	<b>Page</b>
• Combined TPS22910A, TPS22912C, and TPS22913B/C datasheets. ....	1

## 6 Device Comparison Table

DEVICE	$r_{ON}$ (typ) at 3.3 V	RISE TIME at 3.3V (typ)	QUICK OUTPUT DISCHARGE	MAXIMUM OUTPUT CURRENT	ENABLE
TPS22910A	61 m $\Omega$	1 $\mu$ s	No	2 A	Active Low
TPS22912C	61 m $\Omega$	1000 $\mu$ s	No	2 A	Active High
TPS22913B	61 m $\Omega$	66 $\mu$ s	Yes	2 A	Active High
TPS22913C	61 m $\Omega$	660 $\mu$ s	Yes	2 A	Active High

## 7 Pin Configuration and Functions



**Table 1. Pin Assignments**

<b>B</b>	ON	GND
<b>A</b>	VIN	VOUT
	<b>2</b>	<b>1</b>

### Pin Functions

PIN		I/O	DESCRIPTION
NAME	NO.		
VOUT	A1	O	Switch output
VIN	A2	I	Switch input, use a bypass capacitor (ceramic) to ground.
GND	B1	–	Ground
ON	B2	I	Switch control input. Do not leave floating

## 8 Specifications

### 8.1 Absolute Maximum Ratings

		MIN	MAX	UNIT
$V_{IN}$	Input voltage range	-0.3	6	V
$V_{OUT}$	Output voltage range	-0.3	6	V
$V_{ON}$	Input voltage range	-0.3	6	V
$I_{MAX}$	Maximum continuous switch current		2	A
$I_{PLS}$	Maximum pulsed switch current, pulse < 300 $\mu$ s, 2% duty cycle		2.5	A
$T_A$	Operating free-air temperature range	-40	85	$^{\circ}$ C
$T_J$	Maximum junction temperature		125	$^{\circ}$ C
$T_{stg}$	Storage temperature range	-65	150	$^{\circ}$ C

### 8.2 ESD Ratings

		VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	$\pm 2000$	V
		$\pm 1000$	

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process. Manufacturing with less than 500-V HBM is possible with the necessary precautions. Pins listed as  $\pm 2000$  V may actually have higher performance.
- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process. Manufacturing with less than 250-V CDM is possible with the necessary precautions. Pins listed as  $\pm 1000$  V may actually have higher performance.

### 8.3 Recommended Operating Conditions

			MIN	MAX	UNIT
$V_{IN}$	Input voltage range		1.4	5.5	V
$V_{ON}$	ON voltage range		0	5.5	V
$V_{OUT}$	Output voltage range			$V_{IN}$	
$V_{IH}$	High-level input voltage, ON	$V_{IN} = 1.4$ V to 5.5 V	1.1	5.5	V
$V_{IL}$	Low-level input voltage, ON	$V_{IN} = 3.61$ V to 5.5 V		0.6	V
		$V_{IN} = 1.4$ V to 3.6 V		0.4	V
$C_{IN}$	Input capacitor		1 <sup>(1)</sup>		$\mu$ F

- (1) Refer to the application section.

### 8.4 Thermal Information

THERMAL METRIC <sup>(1)</sup>		TPS22910	TPS22912	TPS22913	UNIT
		CSP	CSP	CSP	
		4 PINS	4 PINS	4 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	189.1	189.1	189.1	$^{\circ}$ C/W
$R_{\theta Jctop}$	Junction-to-case (top) thermal resistance	1.9	1.9	1.9	
$R_{\theta JB}$	Junction-to-board thermal resistance	36.8	36.8	36.8	
$\Psi_{JT}$	Junction-to-top characterization parameter	11.3	11.3	11.3	
$\Psi_{JB}$	Junction-to-board characterization parameter	36.8	36.8	36.8	

- (1) For more information about traditional and new thermal metrics, see the *IC Package Thermal Metrics* application report, [SPRA953](#).

## 8.5 Electrical Characteristics

The electrical characteristics in this section apply to all devices unless otherwise noted. For TPS22910A  $V_{ON} = 0$  V where enabled and  $V_{ON} = V_{IN}$  where disabled. For TPS22912C and TPS22913B/C  $V_{ON} = V_{IN}$  where enabled and  $V_{ON} = 0$  V where disabled.  $V_{IN} = 1.4$  V to 5.5 V,  $T_A = -40^{\circ}\text{C}$  to  $85^{\circ}\text{C}$  (unless otherwise noted)

PARAMETER		TEST CONDITIONS	$T_A$	MIN	TYP	MAX	UNIT
$I_{IN}$	Quiescent current	$I_{OUT} = 0$ mA, $V_{IN} = 5.25$ V, $V_{ON} = \text{Enabled}$	Full		2	10	$\mu\text{A}$
		$I_{OUT} = 0$ mA, $V_{IN} = 4.2$ V, $V_{ON} = \text{Enabled}$			2	7.0	
		$I_{OUT} = 0$ mA, $V_{IN} = 3.6$ V, $V_{ON} = \text{Enabled}$			2	7.0	
		$I_{OUT} = 0$ mA, $V_{IN} = 2.5$ V, $V_{ON} = \text{Enabled}$			0.9	5	
		$I_{OUT} = 0$ mA, $V_{IN} = 1.5$ V, $V_{ON} = \text{Enabled}$			0.7	5	
$I_{IN(\text{off})}$	Off supply current	$R_L = 1$ M $\Omega$ , $V_{IN} = 5.25$ V, $V_{ON} = \text{Disabled}$	Full		1.2	10	$\mu\text{A}$
		$R_L = 1$ M $\Omega$ , $V_{IN} = 4.2$ V, $V_{ON} = \text{Disabled}$			0.2	7.0	
		$R_L = 1$ M $\Omega$ , $V_{IN} = 3.6$ V, $V_{ON} = \text{Disabled}$			0.1	7.0	
		$R_L = 1$ M $\Omega$ , $V_{IN} = 2.5$ V, $V_{ON} = \text{Disabled}$			0.1	5	
		$R_L = 1$ M $\Omega$ , $V_{IN} = 1.5$ V, $V_{ON} = \text{Disabled}$			0.1	5	
$I_{IN(\text{Leakage})}$	Leakage current	$V_{OUT} = 0$ V, $V_{IN} = 5.25$ V, $V_{ON} = \text{Disabled}$	Full		1.2	10	$\mu\text{A}$
		$V_{OUT} = 0$ V, $V_{IN} = 4.2$ V, $V_{ON} = \text{Disabled}$			0.2	7.0	
		$V_{OUT} = 0$ V, $V_{IN} = 3.6$ V, $V_{ON} = \text{Disabled}$			0.1	7.0	
		$V_{OUT} = 0$ V, $V_{IN} = 2.5$ V, $V_{ON} = \text{Disabled}$			0.1	5	
		$V_{OUT} = 0$ V, $V_{IN} = 1.5$ V, $V_{ON} = \text{Disabled}$			0.1	5	
$r_{ON}$	On-resistance	$V_{IN} = 5.25$ V, $I_{OUT} = -200$ mA	25 $^{\circ}\text{C}$		60	80	$\text{m}\Omega$
			Full			110	
		$V_{IN} = 5.0$ V, $I_{OUT} = -200$ mA	25 $^{\circ}\text{C}$		60	80	
			Full			110	
		$V_{IN} = 4.2$ V, $I_{OUT} = -200$ mA	25 $^{\circ}\text{C}$		60	80	
			Full			110	
		$V_{IN} = 3.3$ V, $I_{OUT} = -200$ mA	25 $^{\circ}\text{C}$		60.7	80	
			Full			110	
		$V_{IN} = 2.5$ V, $I_{OUT} = -200$ mA	25 $^{\circ}\text{C}$		63.4	90	
			Full			120	
		$V_{IN} = 1.8$ V, $I_{OUT} = -200$ mA	25 $^{\circ}\text{C}$		74.2	100	
			Full			130	
		$V_{IN} = 1.5$ V, $I_{OUT} = -200$ mA	25 $^{\circ}\text{C}$		83.9	120	
			Full			150	
RPD <sup>(1)</sup>	Output pull down resistance	$V_{IN} = 3.3$ V, $I_{OUT} = 30$ mA, $V_{ON} = 0$	25 $^{\circ}\text{C}$		153	200	$\Omega$
UVLO	Under voltage lockout	$V_{IN}$ increasing, $V_{ON} = 0$ V, $I_{OUT} = -100$ mA	Full			1.2	V
				$V_{IN}$ decreasing, $V_{ON} = 0$ V, $R_L = 10$ $\Omega$	0.50		
$I_{ON}$	ON input leakage current	$V_{ON} = 1.4$ V to 5.25 V or GND	Full			1	$\mu\text{A}$
$V_{RCP}$	Reverse current voltage threshold	TPS22910A, TPS22913B/C			44		mV
		TPS22912C			54		
$t_{\text{DELAY}}$	Reverse current response delay	$V_{IN} = 5$ V			10		$\mu\text{s}$
$I_{RCP(\text{leak})}$	Reverse current protection leakage after reverse current event.	$V_{OUT} - V_{IN} > V_{RCP}$	25 $^{\circ}\text{C}$		0.3		$\mu\text{A}$

(1) Only applies to the TPS22913B/C devices

## 8.6 Switching Characteristics, Typical

PARAMETER		TEST CONDITION	TPS22910A	TPS22912C	TPS22913B	TPS22913C	UNIT
<b>VIN = 5 V, TA = 25°C (unless otherwise noted)</b>							
t <sub>ON</sub>	Turn-ON time	R <sub>L</sub> = 10 Ω, C <sub>L</sub> = 0.1 μF	2	840	76	770	μs
t <sub>OFF</sub>	Turn-OFF time	R <sub>L</sub> = 10 Ω, C <sub>L</sub> = 0.1 μF	5.5	6.6	6.6	6.6	
t <sub>R</sub>	VOUT rise time	R <sub>L</sub> = 10 Ω, C <sub>L</sub> = 0.1 μF	1	912	82	838	
t <sub>F</sub>	VOUT fall time	R <sub>L</sub> = 10 Ω, C <sub>L</sub> = 0.1 μF	3	3	3	3	
<b>VIN = 3.3 V, TA = 25°C (unless otherwise noted)</b>							
t <sub>ON</sub>	Turn-ON time	R <sub>L</sub> = 10 Ω, C <sub>L</sub> = 0.1 μF	2.5	1147	102	1048	μs
t <sub>OFF</sub>	Turn-OFF time	R <sub>L</sub> = 10 Ω, C <sub>L</sub> = 0.1 μF	7	8.6	8.5	8.6	
t <sub>R</sub>	VOUT rise time	R <sub>L</sub> = 10 Ω, C <sub>L</sub> = 0.1 μF	1	1030	97	980	
t <sub>F</sub>	VOUT fall time	R <sub>L</sub> = 10 Ω, C <sub>L</sub> = 0.1 μF	3.5	3	3	3	
<b>VIN = 1.5 V, TA = 25°C (unless otherwise noted)</b>							
t <sub>ON</sub>	Turn-ON time	R <sub>L</sub> = 10 Ω, C <sub>L</sub> = 0.1 μF	4.5	2513	234	2344	μs
t <sub>OFF</sub>	Turn-OFF time	R <sub>L</sub> = 10 Ω, C <sub>L</sub> = 0.1 μF	16.5	17.4	17	18	
t <sub>R</sub>	VOUT rise time	R <sub>L</sub> = 10 Ω, C <sub>L</sub> = 0.1 μF	2	1970	244	1823	
t <sub>F</sub>	VOUT fall time	R <sub>L</sub> = 10 Ω, C <sub>L</sub> = 0.1 μF	7	6.5	6.5	6.5	

## 8.7 Typical DC Characteristics

The typical characteristics curves in this section apply to all devices unless otherwise noted.

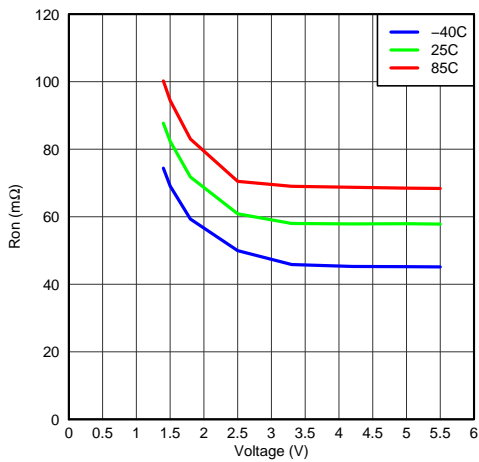


Figure 1. On-State Resistance vs Input Voltage

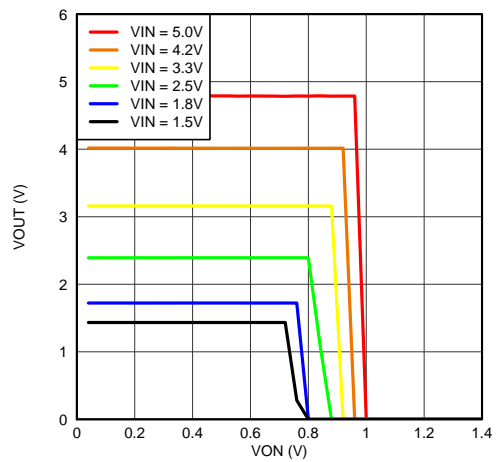


Figure 2. TPS22910A On Input Threshold (Active Low)

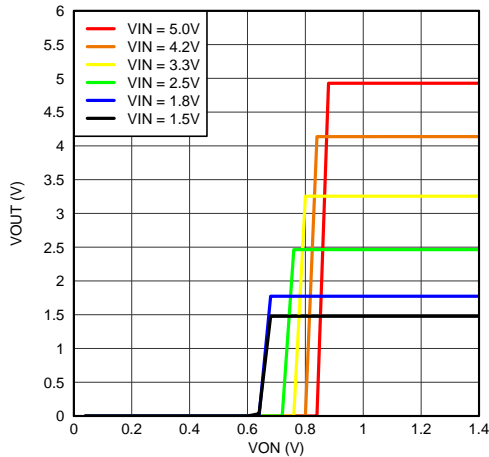


Figure 3. TPS22912C and TPS22913B/C On Input Threshold (Active High)

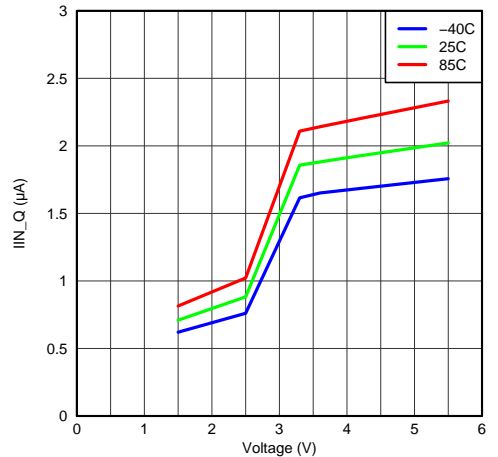


Figure 4. Input Current, Quiescent vs Input Voltage

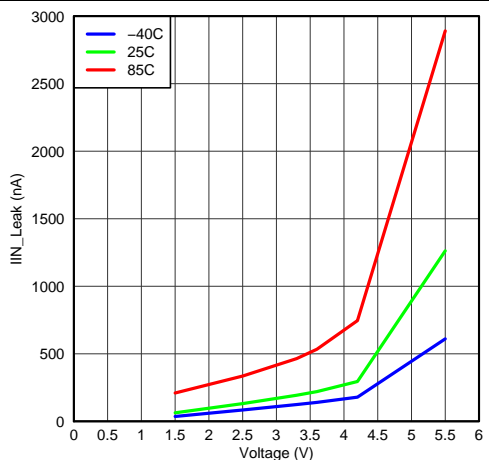


Figure 5. Input Current, Leak vs Input Voltage

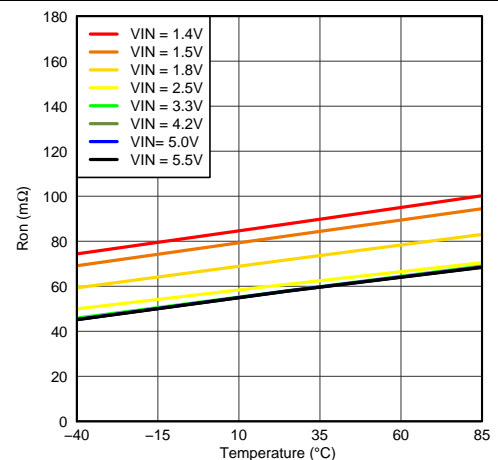


Figure 6. On-state Resistance vs Temperature

### Typical DC Characteristics (continued)

The typical characteristics curves in this section apply to all devices unless otherwise noted.

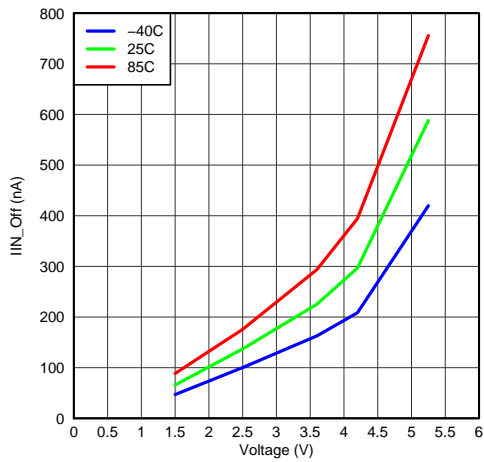


Figure 7. Input Current, Off vs Input Voltage

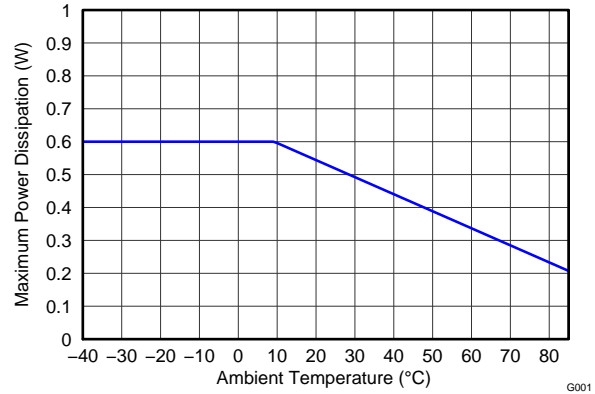


Figure 8. Allowable Power Dissipation

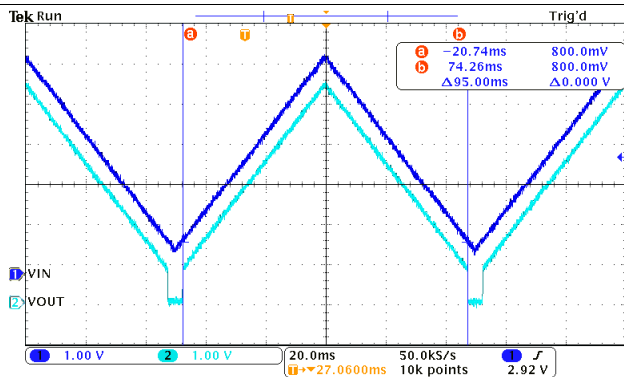


Figure 9. Under Voltage Lockout Response (IOUT = -100mA)

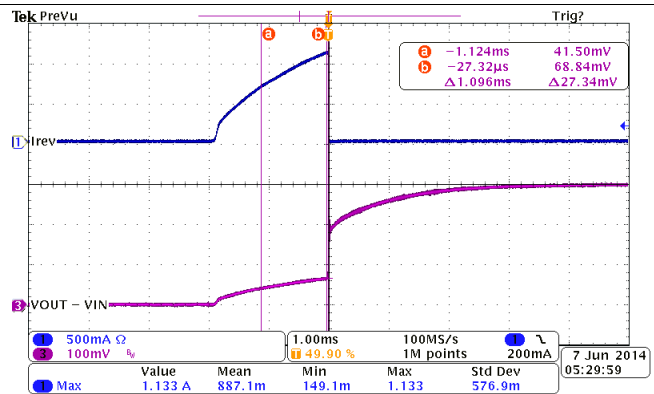


Figure 10. Full-Time Reverse Current Protection (VIN = 3.0 V, VOUT Ramp up From 3.0 V to 3.3 V)



### 8.8 Typical AC Characteristics, TPS22910A

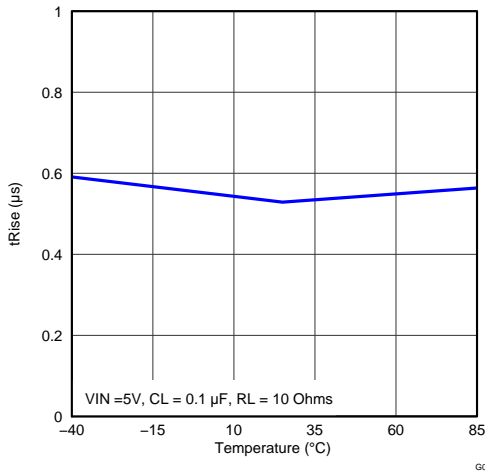


Figure 11. Rise Time vs Temperature

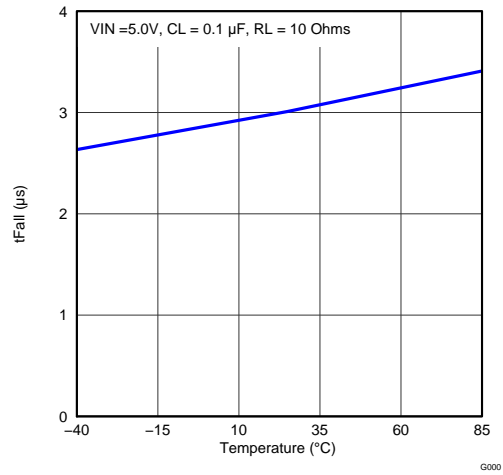


Figure 12. Fall Time vs Temperature

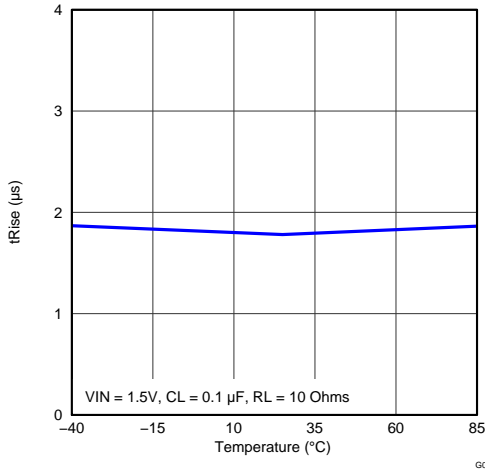


Figure 13. Rise Time vs Temperature

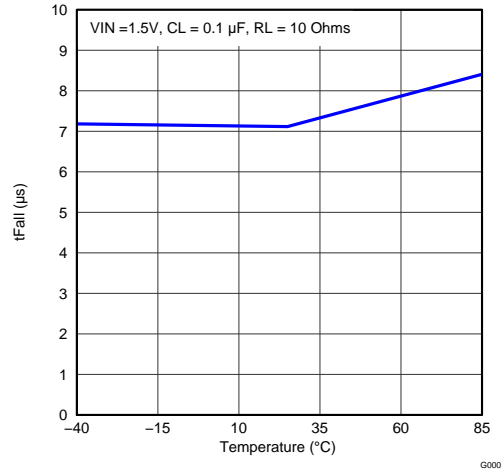


Figure 14. Fall Time vs Temperature

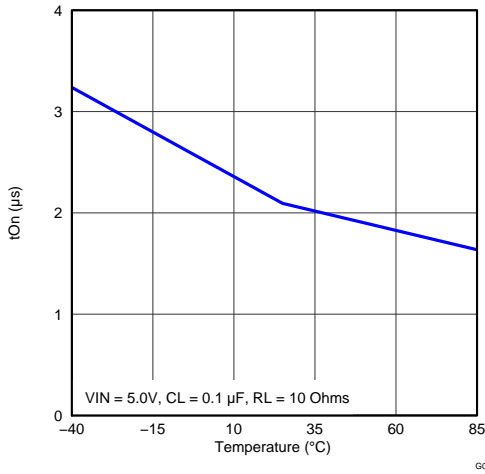


Figure 15. Turn-on Time vs Temperature

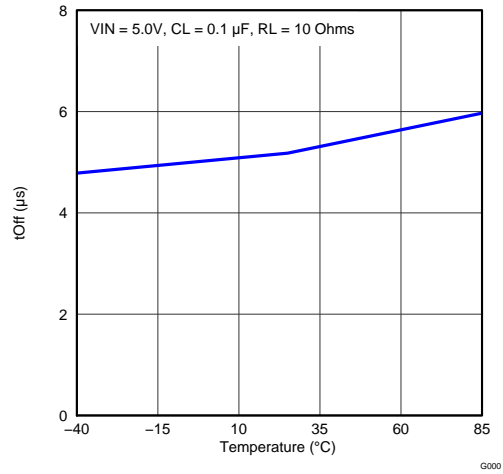
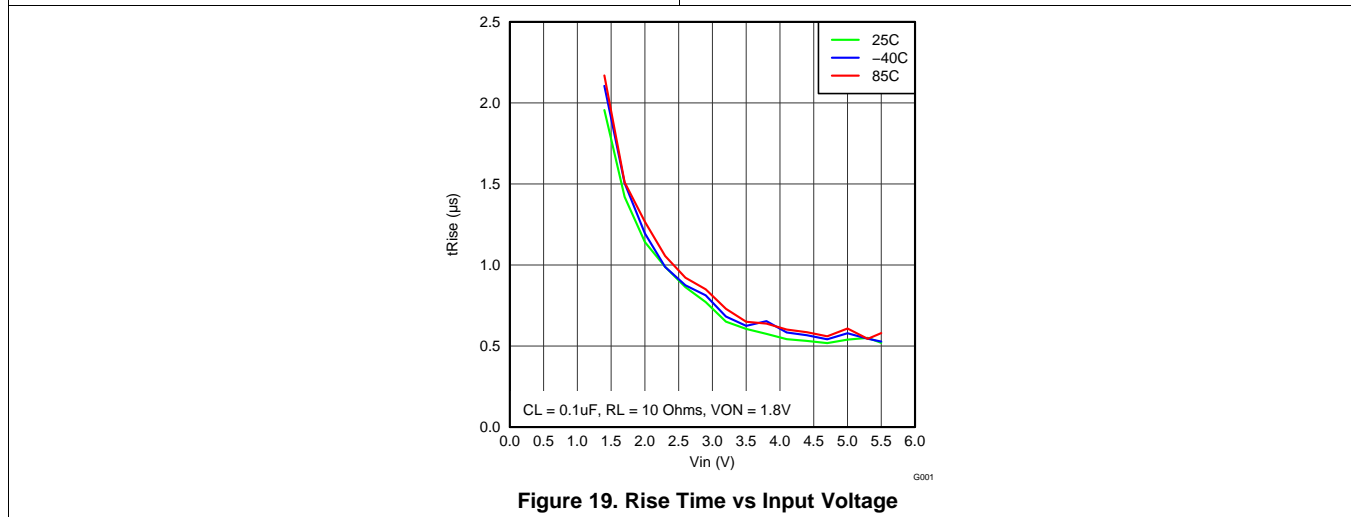
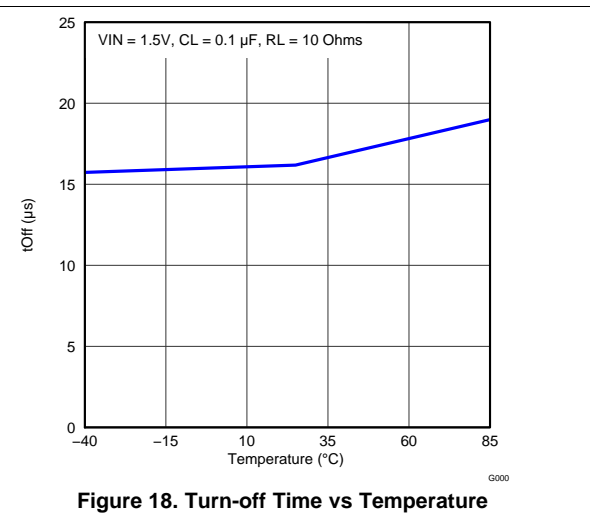
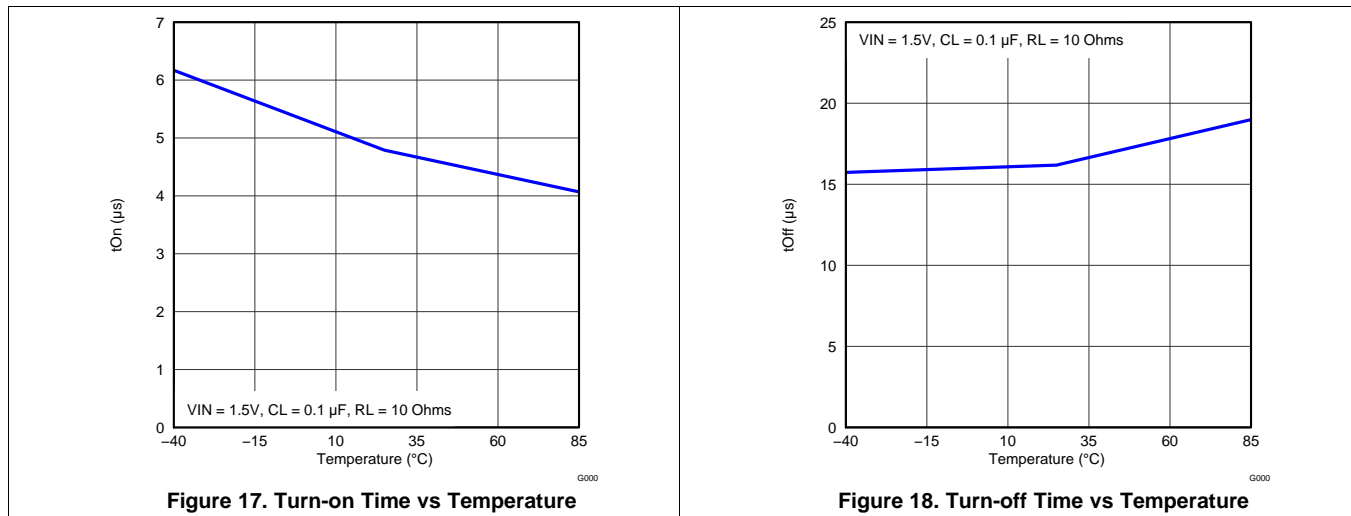


Figure 16. Turn-off Time vs Temperature

**Typical AC Characteristics, TPS22910A (continued)**



### 8.9 Typical AC Characteristics, TPS22912C

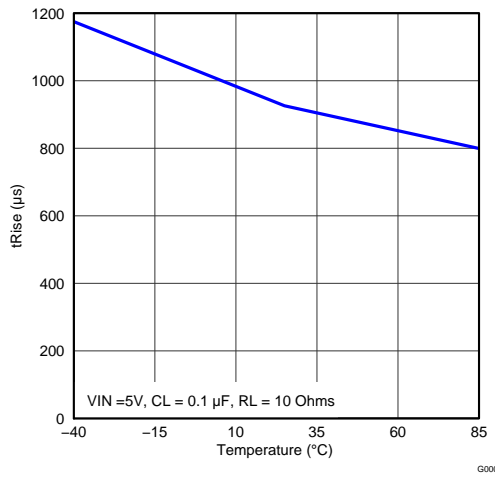


Figure 20. Rise Time vs Temperature

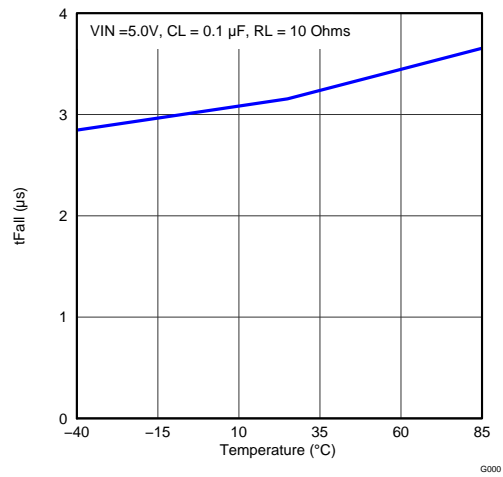


Figure 21. Fall Time vs Temperature

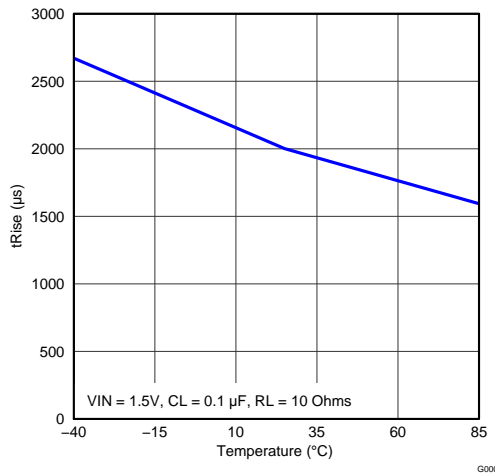


Figure 22. Rise Time vs Temperature

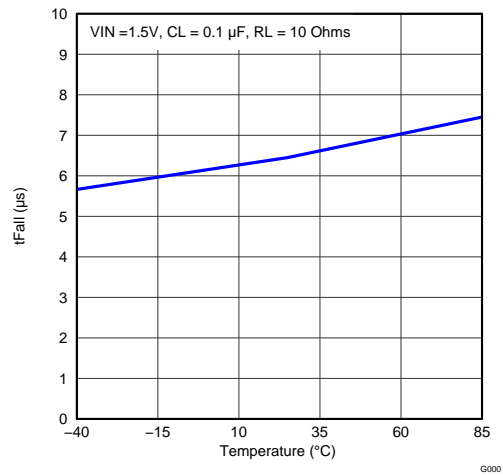


Figure 23. Fall Time vs Temperature

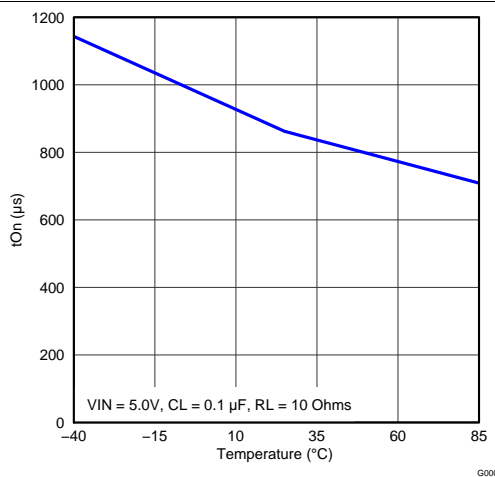


Figure 24. Turn-on Time vs Temperature

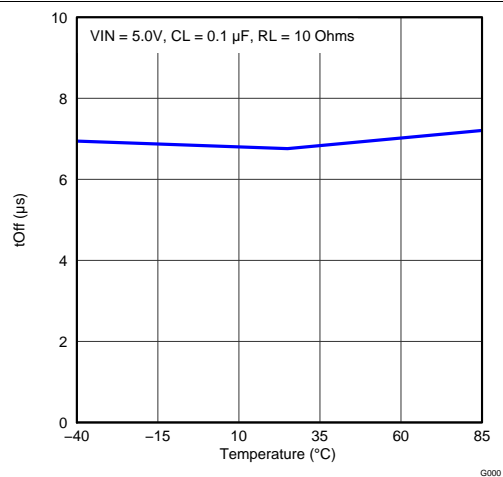
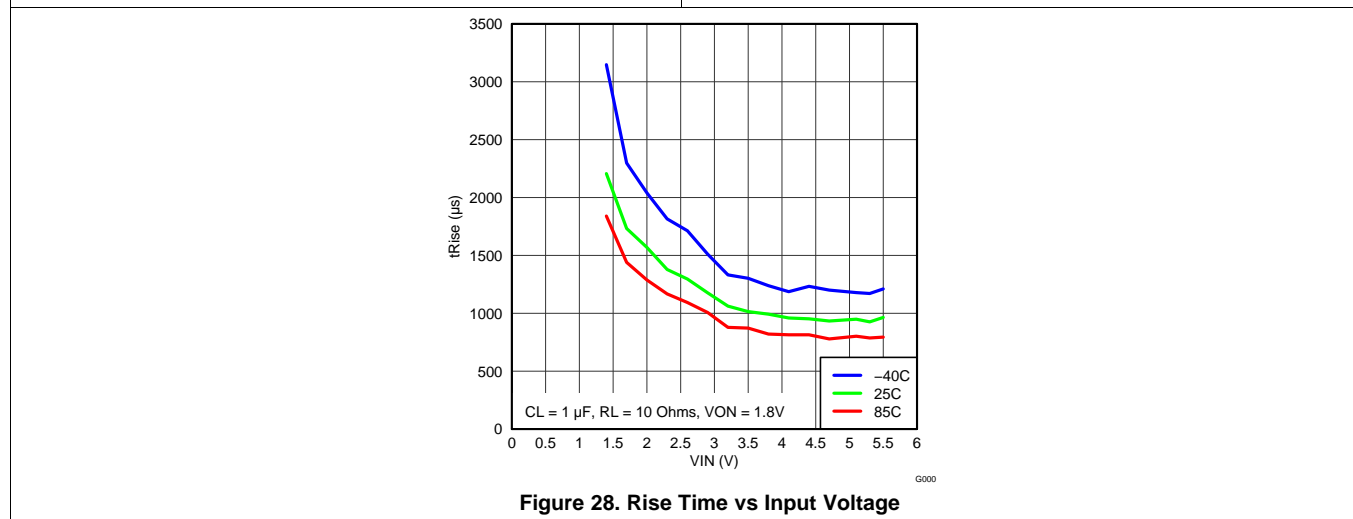
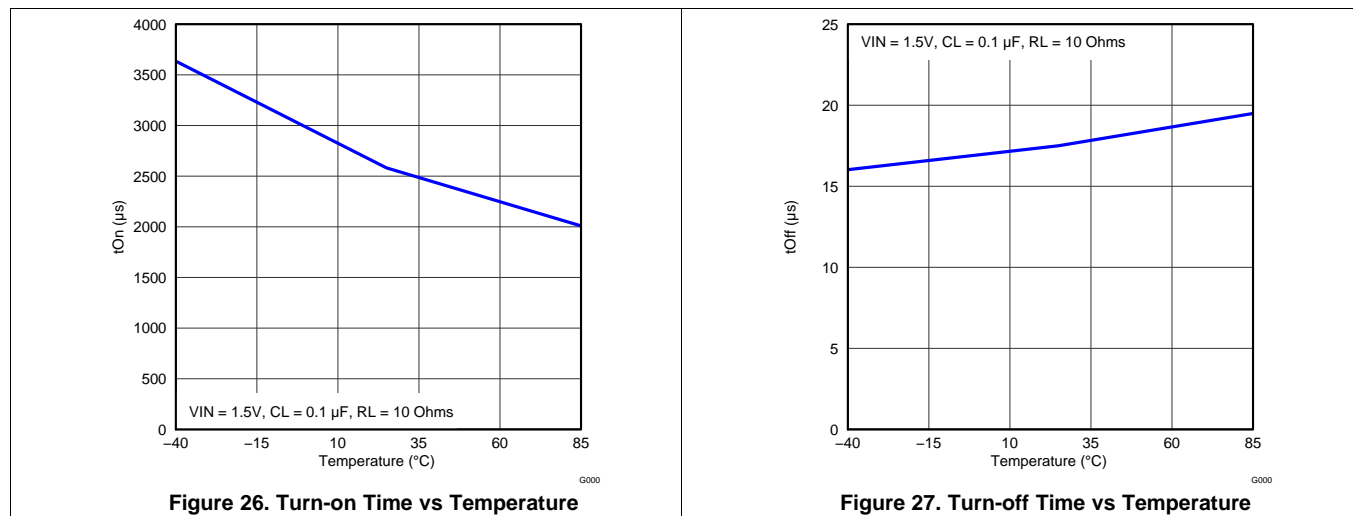


Figure 25. Turn-off Time vs Temperature

**Typical AC Characteristics, TPS22912C (continued)**



### 8.10 Typical AC Characteristics, TPS22913B

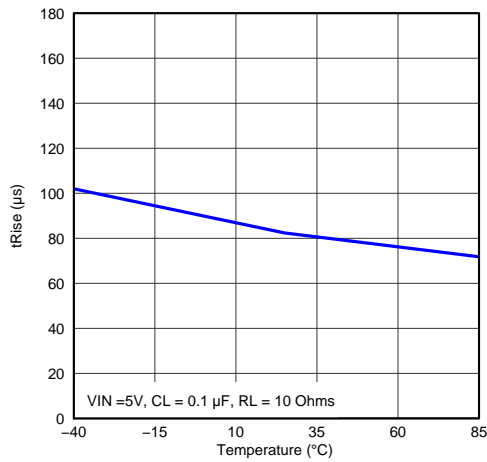


Figure 29. Rise Time vs Temperature

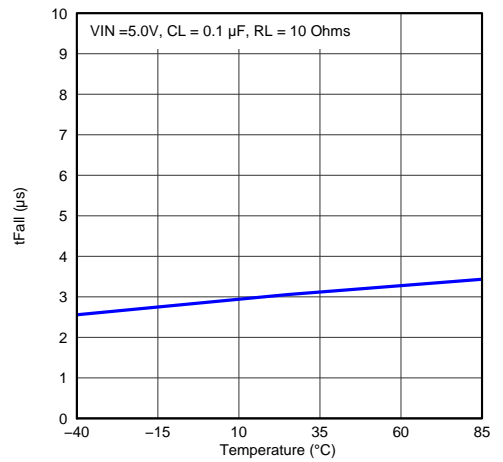


Figure 30. Fall Time vs Temperature

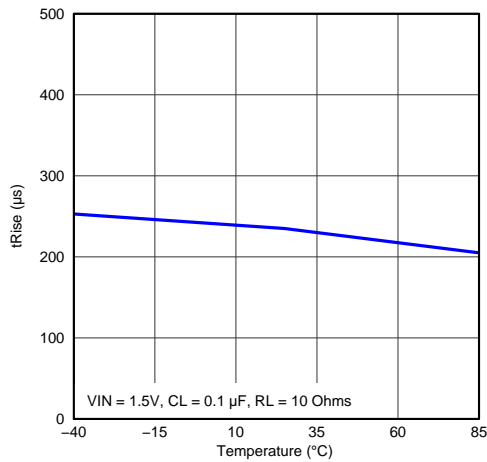


Figure 31. Rise Time vs Temperature

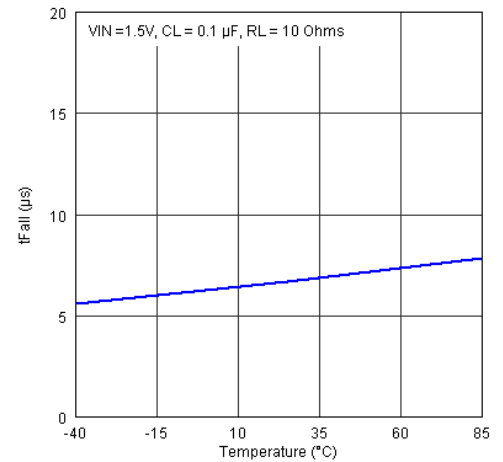


Figure 32. Fall Time vs Temperature

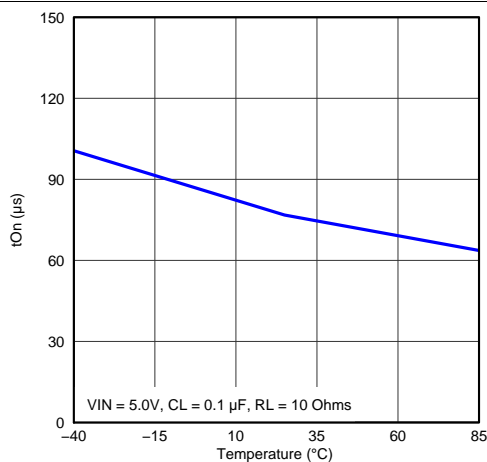


Figure 33. Turn-on Time vs Temperature

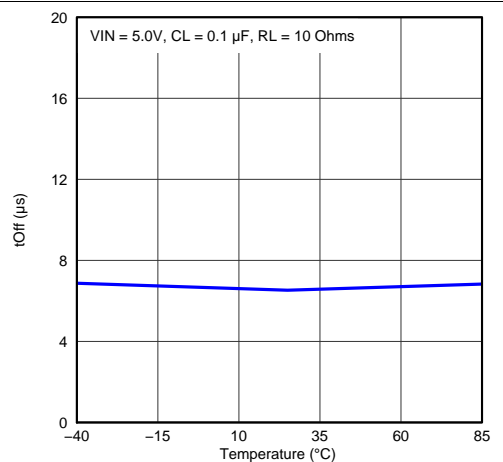
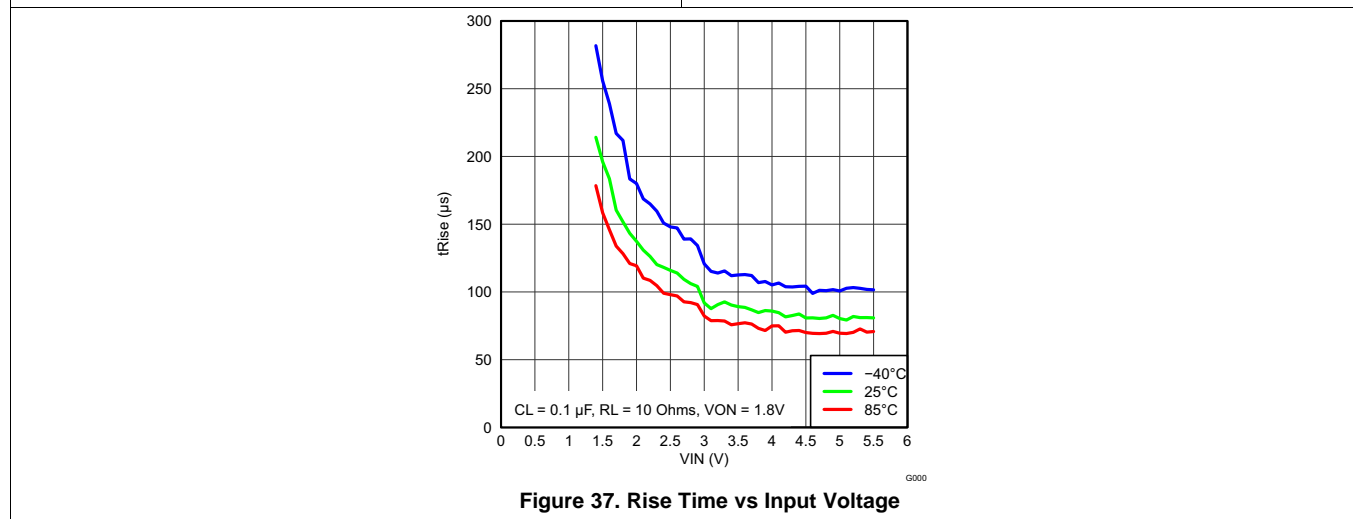
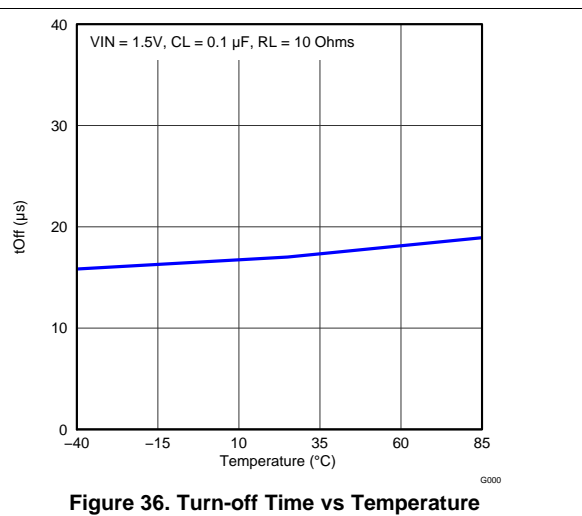
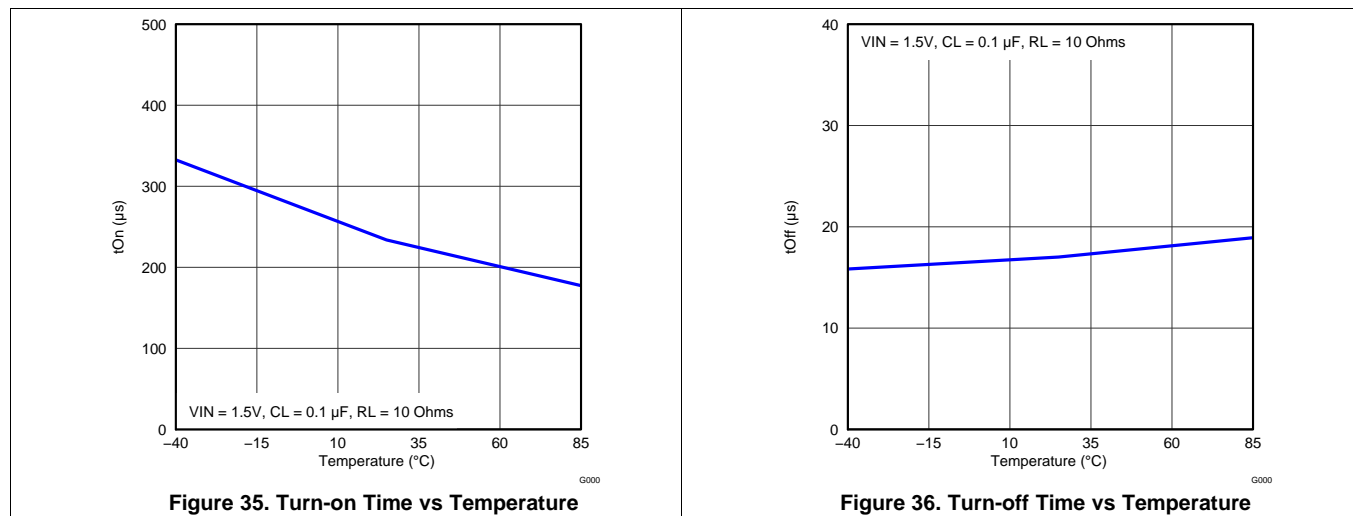


Figure 34. Turn-off Time vs Temperature

Typical AC Characteristics, TPS22913B (continued)



### 8.11 Typical AC Characteristics, TPS22913C

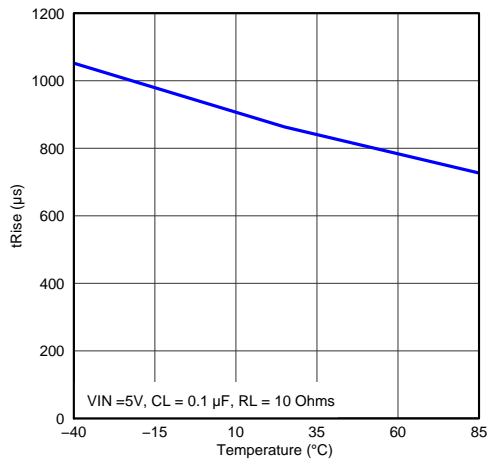


Figure 38. Rise Time vs Temperature

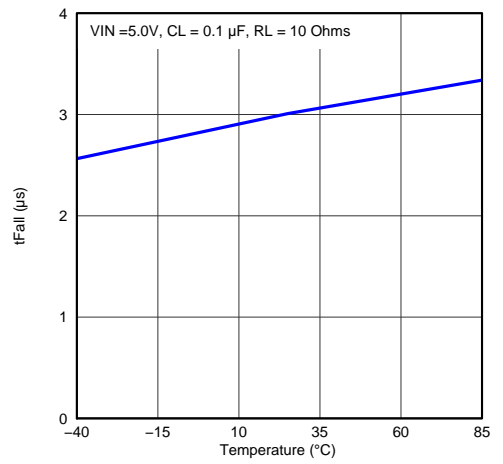


Figure 39. Fall Time vs Temperature

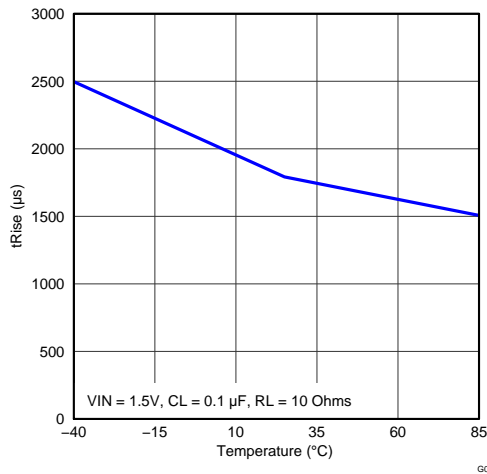


Figure 40. Rise Time vs Temperature

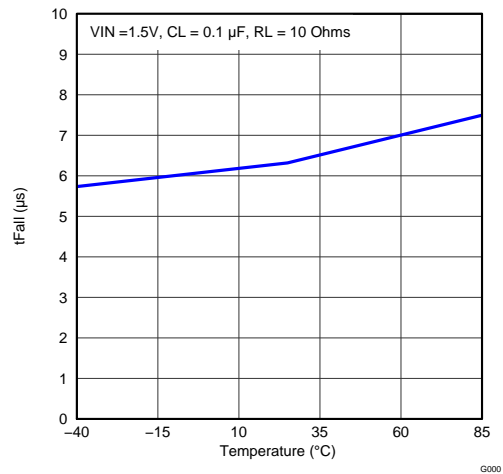


Figure 41. Fall Time vs Temperature

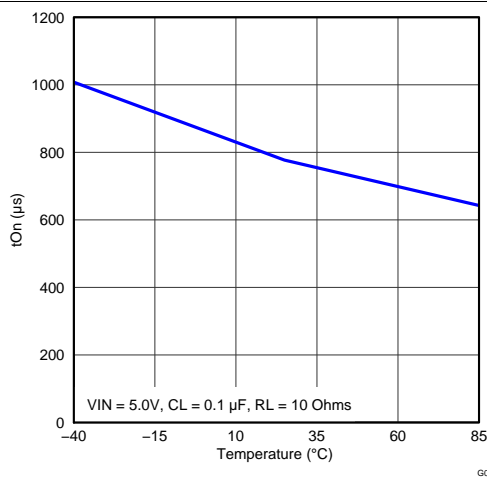


Figure 42. Turn-on Time vs Temperature

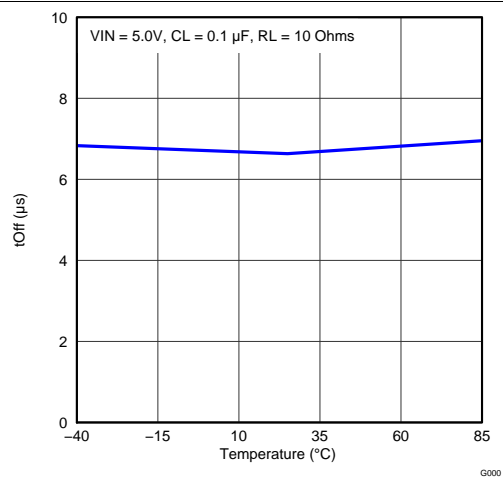


Figure 43. Turn-Off Time vs Temperature

Typical AC Characteristics, TPS22913C (continued)

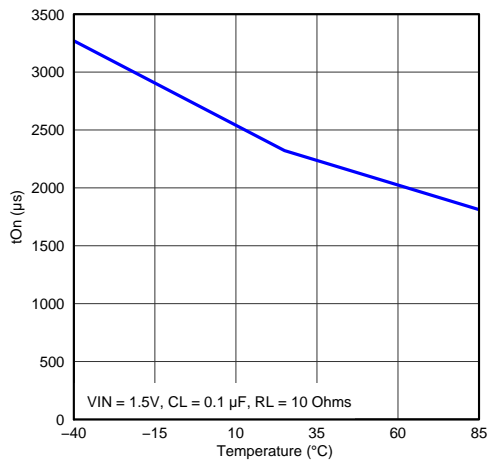


Figure 44. Turn-On Time vs Temperature

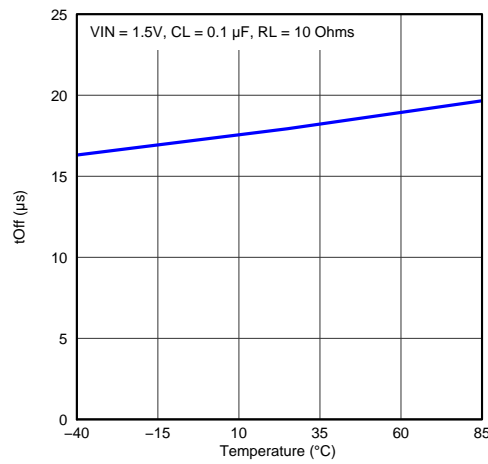


Figure 45. Turn-Off Time vs Temperature

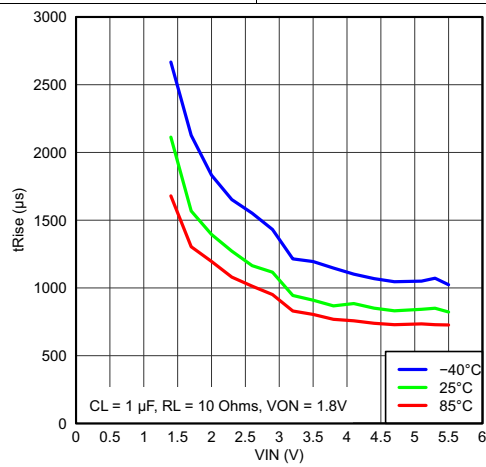
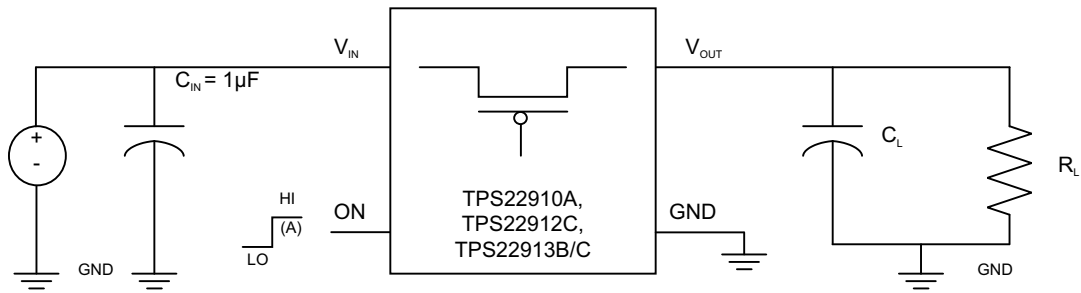


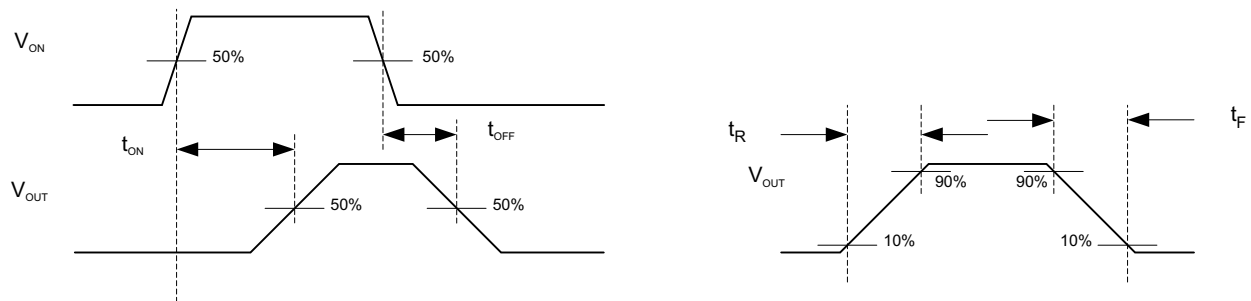
Figure 46. Rise Time vs Input Voltage



## 9 Parameter Measurement Information



**Figure 47. Timing Test Circuit**



- A. Rise and fall times of the control signal is 100 ns.

**Figure 48. Timing Waveforms**

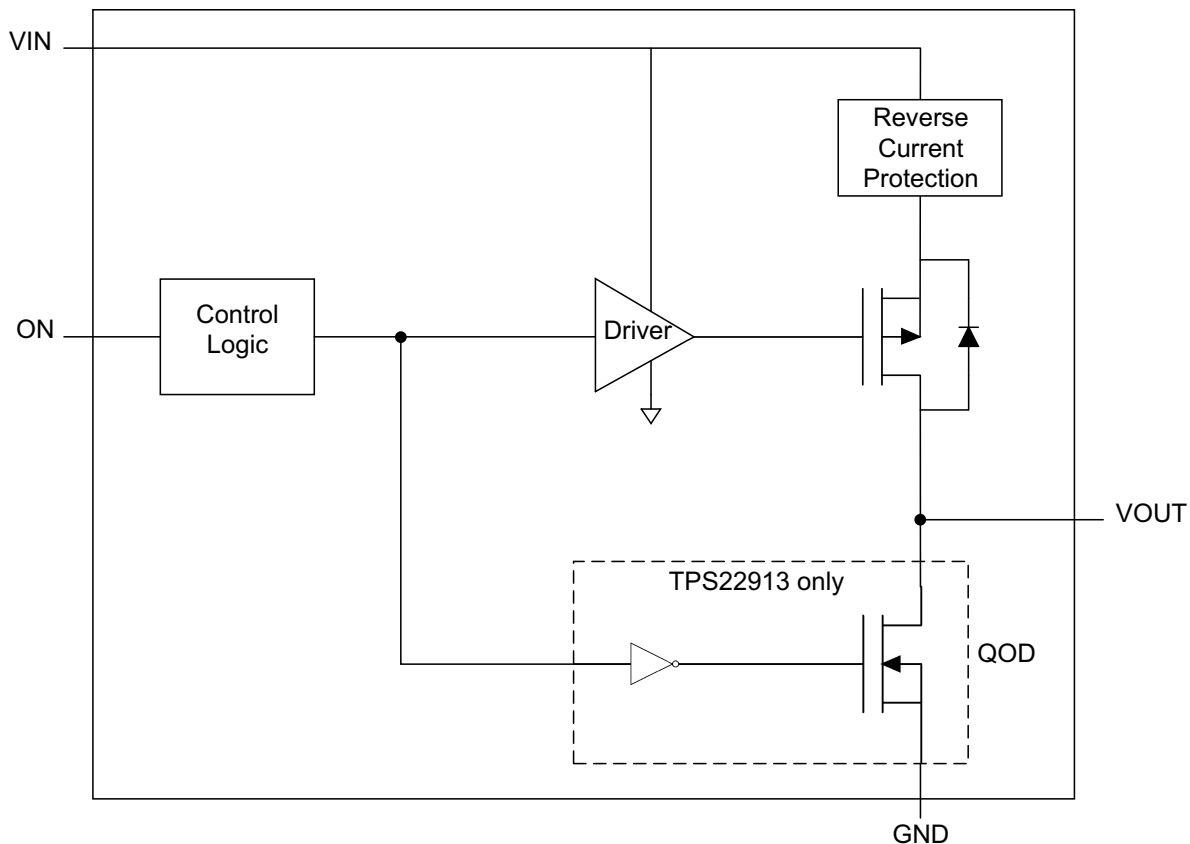
## 10 Detailed Description

### 10.1 Overview

This family of devices are single channel, 2-A load switches in ultra-small, space saving 4-pin WCSP package. These devices implement a low resistance P-channel MOSFET with a controlled rise time for applications that need to limit the inrush current.

These devices are designed to have very low leakage current during off state. This prevents downstream circuits from pulling high standby current from the supply. Integrated control logic, driver, power supply, and output discharge FET eliminates the need for additional external components, which reduces solution size and BOM count.

### 10.2 Functional Block Diagram



### 10.3 Feature Description

#### 10.3.1 On/Off Control

The ON pin controls the state of the switch. The ON pin is compatible with standard GPIO logic threshold. It can be used with any microcontroller with 1.2-V, 1.8-V, 2.5-V, 3.3-V, or 5.5-V GPIO.

#### 10.3.2 Under-Voltage Lockout

Under-voltage lockout protection turns off the switch if the input voltage drops below the under-voltage lockout threshold (UVLO). With the ON pin active, the input voltage rising above the under-voltage lockout threshold will cause a controlled turn-on of the switch to limit current over-shoot.

## Feature Description (continued)

### 10.3.3 Full-Time Reverse Current Protection

In a scenario where  $V_{OUT}$  is greater than  $V_{IN}$ , there is potential for reverse current to flow through the pass FET or the body diode. The devices monitor  $V_{IN}$  and  $V_{OUT}$  voltage levels. When the reverse current voltage threshold ( $V_{RCP}$ ) is exceeded, the switch is disabled (within 10 $\mu$ s typ). Additionally, the body diode is disengaged so as to prevent any reverse current flow to VIN. The peak instantaneous reverse current is the current it takes to activate the reverse current protection. After the reverse current protection has activated due to the peak instantaneous reverse current, the DC (off-state) leakage current from  $V_{OUT}$  and  $V_{IN}$  is referred to as  $I_{RCP(leak)}$  (see Figure 49). The pass FET, and the output voltage ( $V_{OUT}$ ), will resume normal operation when the reverse voltage scenario is no longer present.

The following formula can be used to calculate the amount of peak instantaneous reverse current for a particular application:

$$I_{RC} = \frac{V_{RCP}}{r_{ON(VIN)}}$$

Where,

$I_{RC}$  is the amount of reverse current,

$r_{ON(VIN)}$  is the on-resistance at the VIN of the reverse current condition.

$V_{RCP}$  is the reverse voltage threshold.

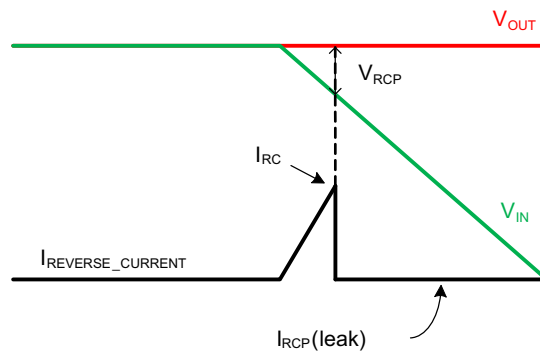


Figure 49. Reverse Current

## 10.4 Device Functional Modes

Table 2 describes what the VOUT pin will be connected to for a particular device as determined by the ON pin

Table 2. VOUT Function Table

ON	TPS22910A	TPS22912C	TPS22913B/C
L	VIN	Open	GND
H	Open	VIN	VIN

## 11 Application and Implementation

### 11.1 Application Information

This section will highlight some of the design considerations when implementing this device in various applications. A PSPICE model for this device is also available in the product page of this device on [www.ti.com](http://www.ti.com) for further aid.

#### 11.1.1 VIN to VOUT Voltage Drop

The VIN to VOUT voltage drop in the device is determined by the  $R_{ON}$  of the device and the load current. The  $R_{ON}$  of the device depends upon the VIN condition of the device. Refer to the  $R_{ON}$  specification of the device in the Electrical Characteristics table of this datasheet. Once the  $R_{ON}$  of the device is determined based upon the VIN conditions, use [Equation 1](#) to calculate the VIN to VOUT voltage drop:

$$\Delta V = I_{LOAD} \times R_{ON} \quad (1)$$

Where,

$\Delta V$  = Voltage drop from VIN to VOUT

$I_{LOAD}$  = Load current

$R_{ON}$  = On-resistance of the device for a specific  $V_{IN}$

An appropriate  $I_{LOAD}$  must be chosen such that the  $I_{MAX}$  specification of the device is not violated.

#### 11.1.2 On/Off Control

The ON pin controls the state of the switch. The ON pin has a low threshold, making it capable of interfacing with low-voltage signals. The ON pin is compatible with standard GPIO logic thresholds. It can be used with any microcontroller with 1.2 V or higher GPIO voltage. This pin cannot be left floating and must be driven either high or low for proper functionality.

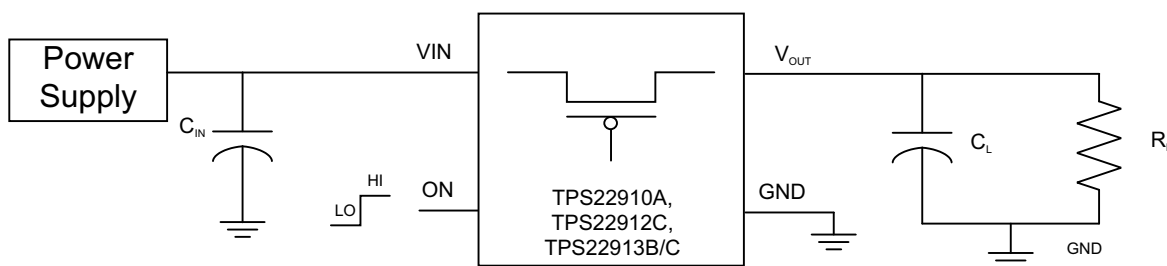
#### 11.1.3 Input Capacitor (Optional)

To limit the voltage drop on the input supply caused by transient inrush currents when the switch turns on into a discharged load capacitor or short-circuit, a capacitor needs to be placed between  $V_{IN}$  and GND. A 1- $\mu$ F ceramic capacitor,  $C_{IN}$ , placed close to the pins, is usually sufficient. Higher values of  $C_{IN}$  can be used to further reduce the voltage drop during high current applications. When switching heavy loads, it is recommended to have an input capacitor about 10 times higher than the output capacitor to avoid excessive voltage drop.

#### 11.1.4 Output Capacitor (Optional)

Due to the integrated body diode in the PMOS switch, a  $C_{IN}$  greater than  $C_L$  is highly recommended. A  $C_L$  greater than  $C_{IN}$  can cause  $V_{OUT}$  to exceed  $V_{IN}$  when the system supply is removed. This could result in current flow through the body diode from  $V_{OUT}$  to  $V_{IN}$ . A  $C_{IN}$  to  $C_L$  ratio of 10 to 1 is recommended for minimizing VIN dip caused by inrush currents during startup, however a 10 to 1 ratio for capacitance is not required for proper functionality of the device. A ratio smaller than 10 to 1 (such as 1 to 1) could cause slightly more  $V_{IN}$  dip upon turn-on due to inrush currents. This can be mitigated by using a device with a longer rise time.

### 11.2 Typical Application



**Figure 50. Typical Application**

## Typical Application (continued)

### 11.2.1 Design Requirements

Design Parameter	Example Value
VIN	1.5 V to 5 V
CL	0.1 $\mu$ F to 1 $\mu$ F
Maximum Acceptable Inrush Current	1 A

### 11.2.2 Detailed Design Procedure

#### 11.2.2.1 Inrush Current

When the switch is enabled, the output capacitors must be charged up from 0-V to VIN voltage. This charge arrives in the form of inrush current. Inrush current can be calculated using the following equation:

$$\text{Inrush Current} = C \times \frac{dv}{dt} \quad (2)$$

Where,

C = Output capacitance

$\frac{dv}{dt}$  = Output slew rate

The TPS22910A, TPS22912C, and TPS22913B/C offer several different rise time options to control the inrush current during turn-on. The appropriate device can be selected based upon the maximum acceptable slew rate which can be calculated using the design requirements and the inrush current equation. An output capacitance of 1.0  $\mu$ F will be used since the inrush follows the following equations:

$$1.0 \text{ A} = 1.0 \text{ } \mu\text{F} \times \frac{dv}{dt} \quad (3)$$

$$\frac{dv}{dt} = 1 \text{ V}/\mu\text{s} \quad (4)$$

To ensure an inrush current of less than 1 A, a device with a slew rate less than 1 V/ $\mu$ s must be used

The TPS22910A has a typical rise time of 1  $\mu$ s at 3.3 V. This results in a slew rate of 3.3 V/ $\mu$ s which is above the 1 V/ $\mu$ s requirement meaning the TPS22910 could not be used to meet the design requirements.

The TPS22913B has a typical rise time of 66  $\mu$ s at 3.3 V. This results in a slew rate of 50 mV/ $\mu$ s which is below the 1 V/ $\mu$ s requirement; therefore, the TPS22913B could be used to meet the design requirements. The TPS22912C or TPS22913C have lower slew rates than the TPS22913B, so they could also be used, but the output would rise more slowly.

### 11.2.3 Application Curves

#### 11.2.3.1 Typical Application Characteristics for TPS22910A

The dark blue curve (Channel 1) represents the VOUT pin of the device. The light blue curve (Channel 2) represents the ON pin of the device.

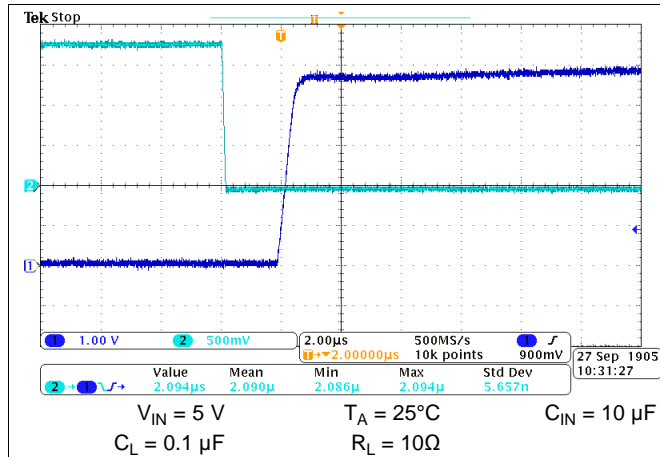


Figure 51. Turn-on Response

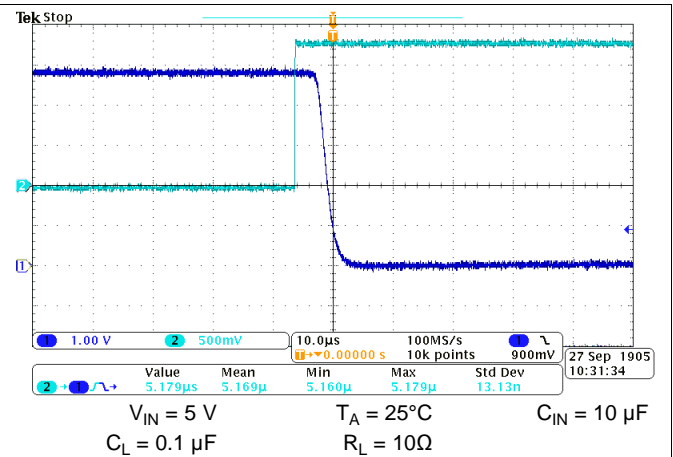


Figure 52. Turn-off Response

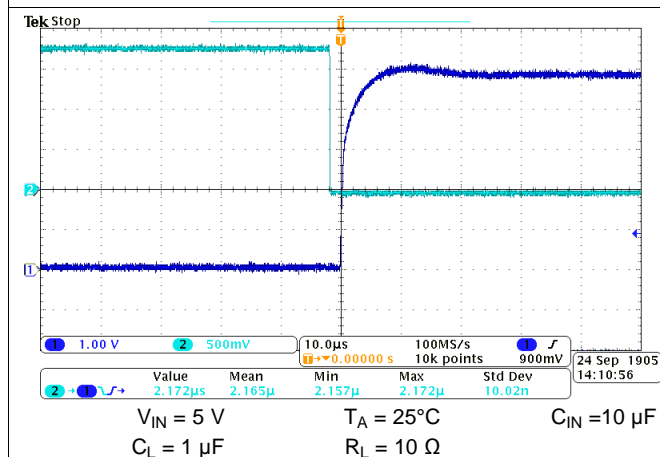


Figure 53. Turn-on Response Time

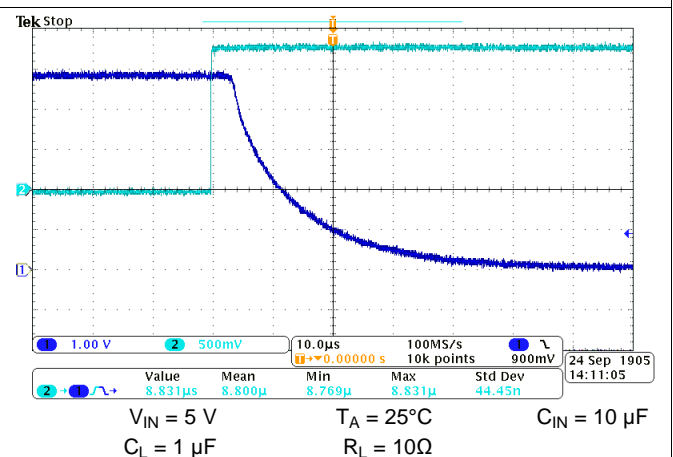


Figure 54. Turn-off Response Time

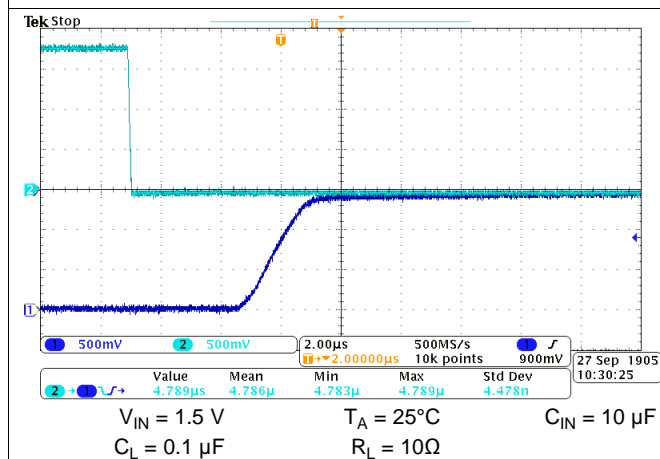


Figure 55. Turn-on Response Time

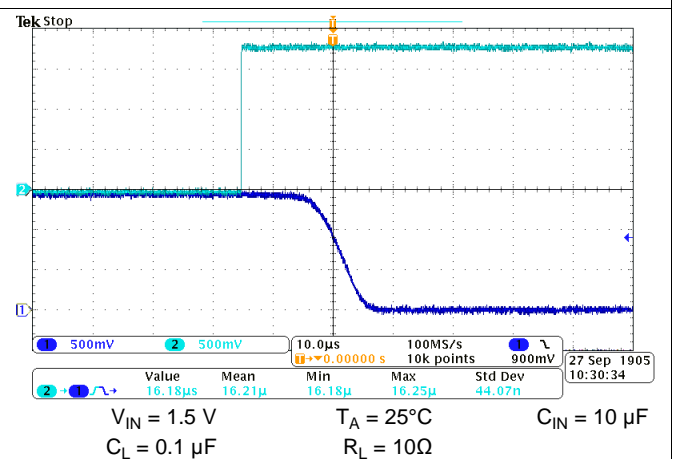
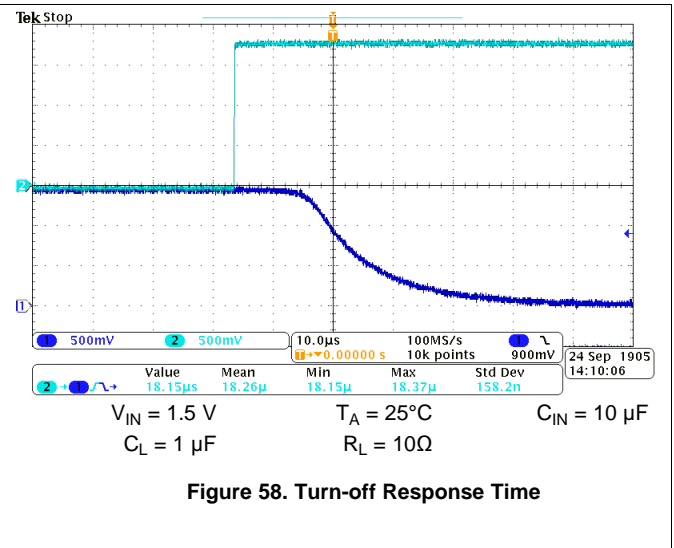
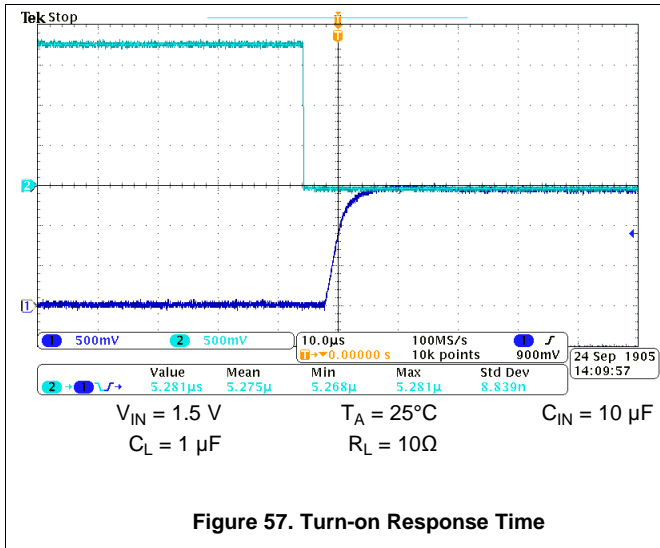


Figure 56. Turn-off Response Time



### 11.2.3.2 Typical Application Characteristics for TPS22912C

The dark blue curve (Channel 1) represents the VOUT pin of the device. The light blue curve (Channel 2) represents the ON pin of the device.

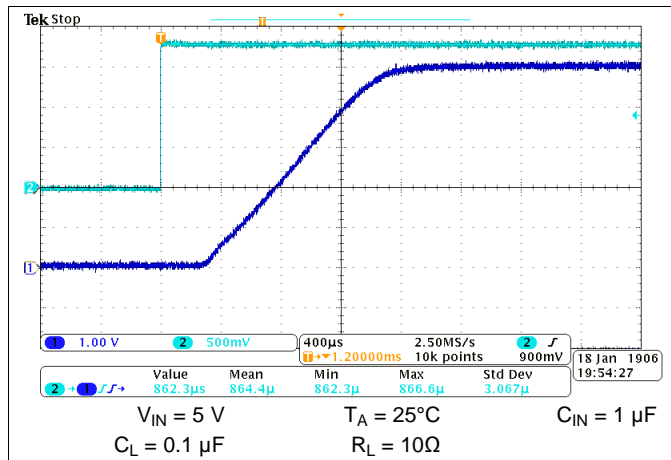


Figure 59. Turn-on Response

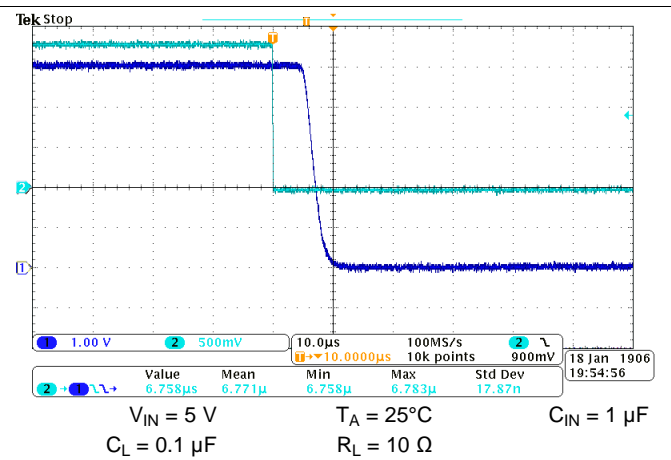


Figure 60. Turn-off Response

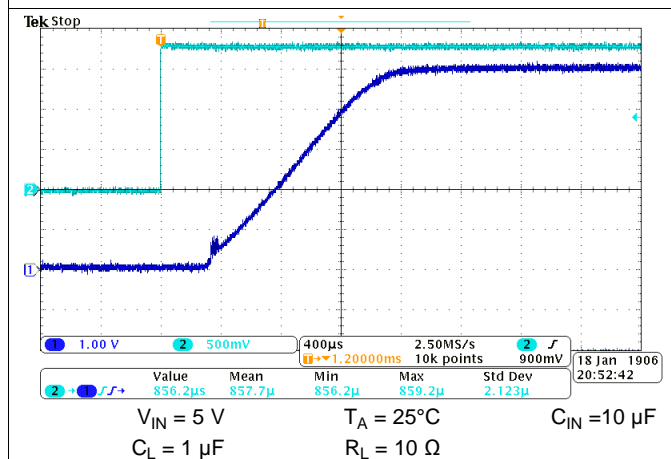


Figure 61. Turn-on Response Time

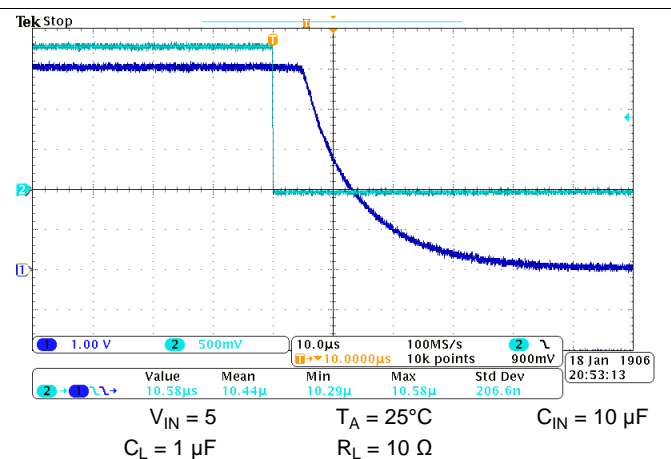


Figure 62. Turn-off Response Time

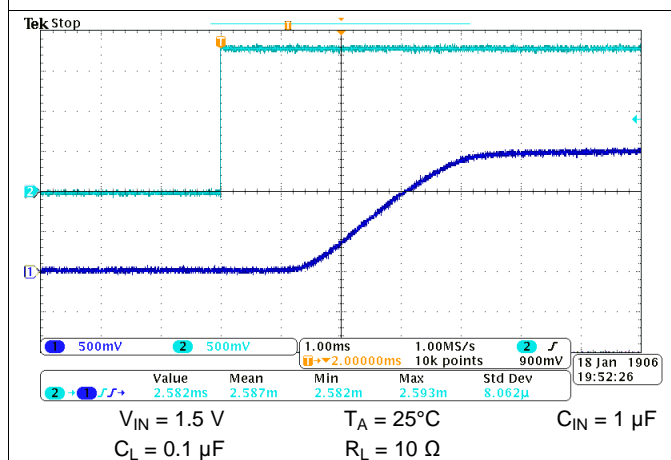


Figure 63. Turn-on Response Time

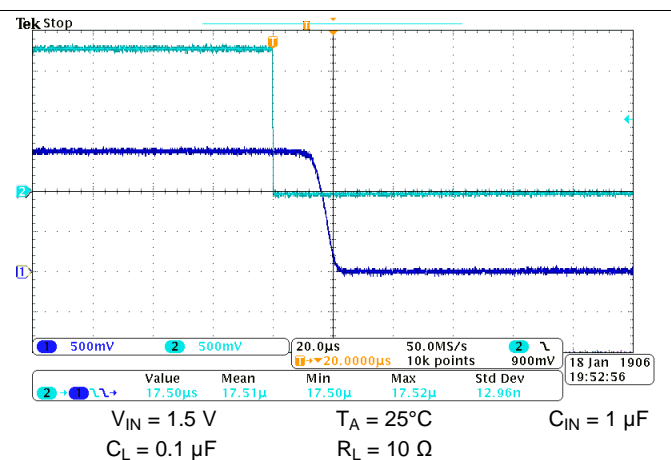
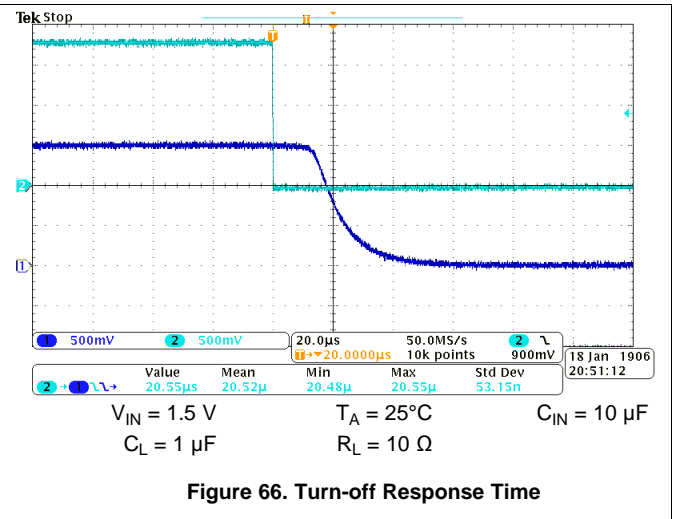
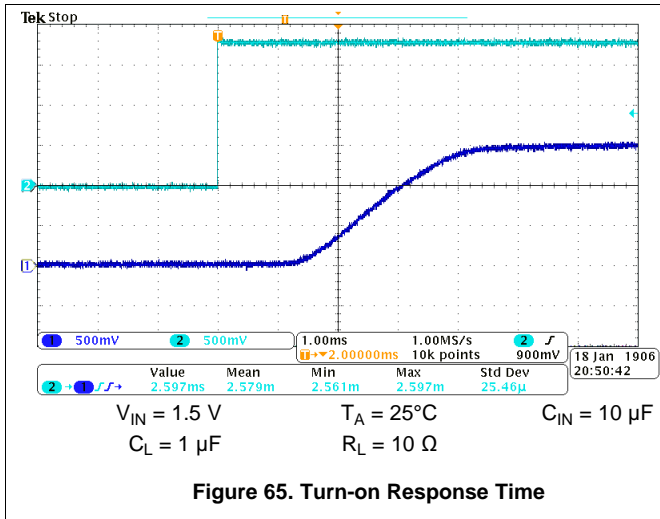


Figure 64. Turn-off Response Time





### 11.2.3.3 Typical Application Characteristics For TPS22913B

The dark blue curve (Channel 1) represents the VOUT pin of the device. The light blue curve (Channel 2) represents the ON pin of the device.

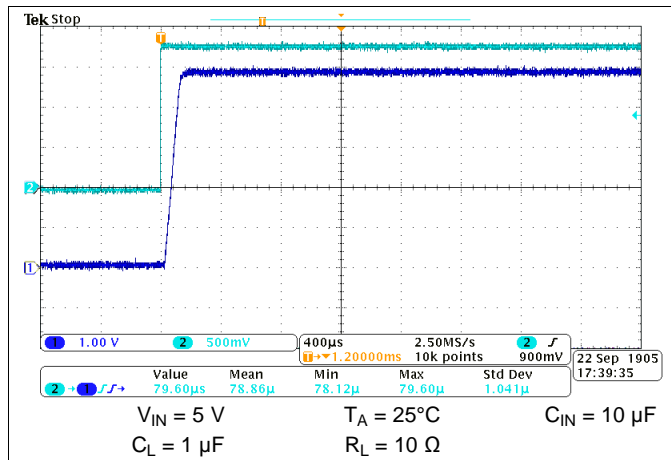


Figure 67. Turn-on Response

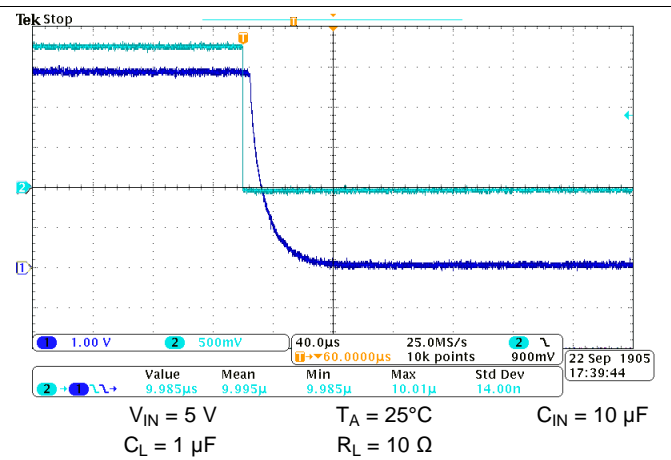


Figure 68. Turn-off Response

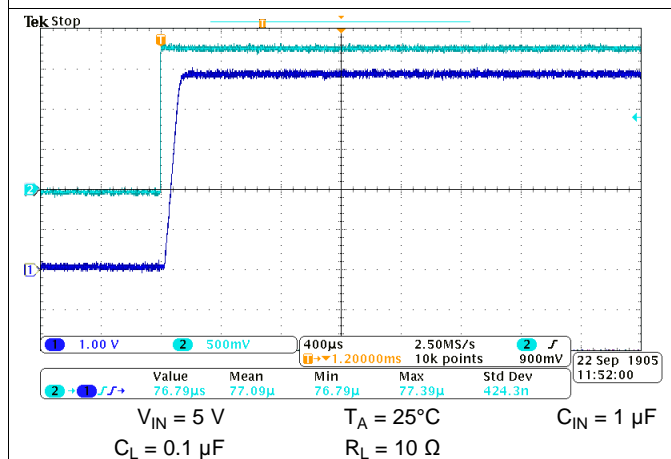


Figure 69. Turn-on Response Time

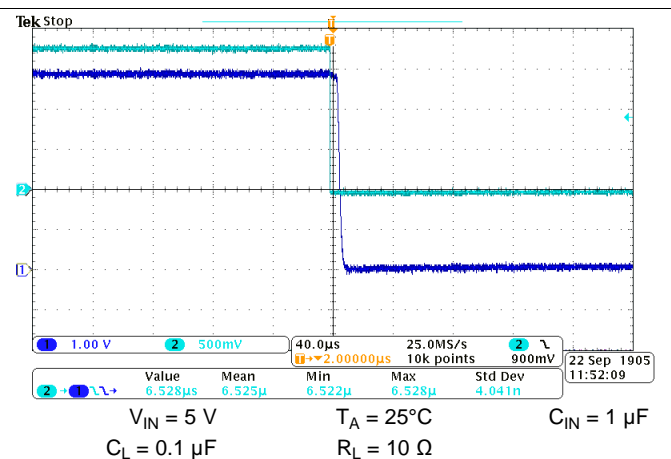


Figure 70. Turn-off Response Time

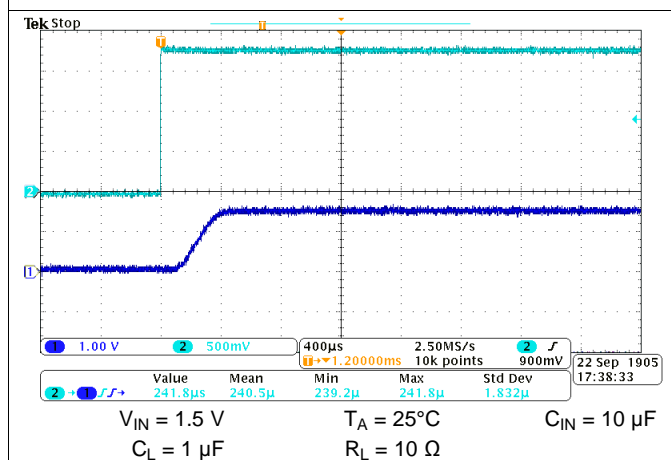


Figure 71. Turn-on Response Time

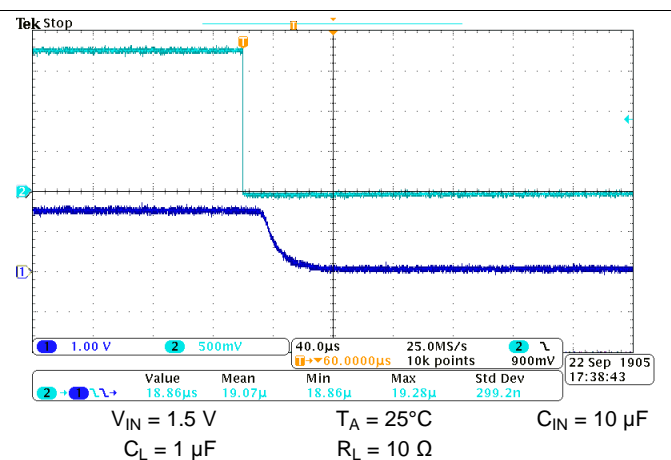
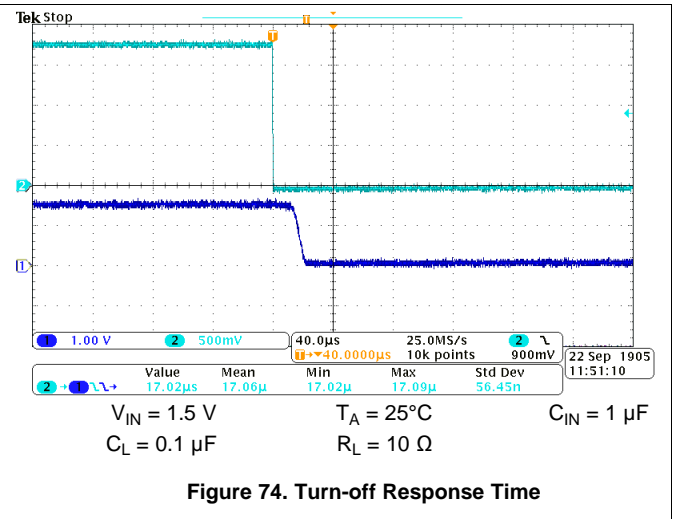
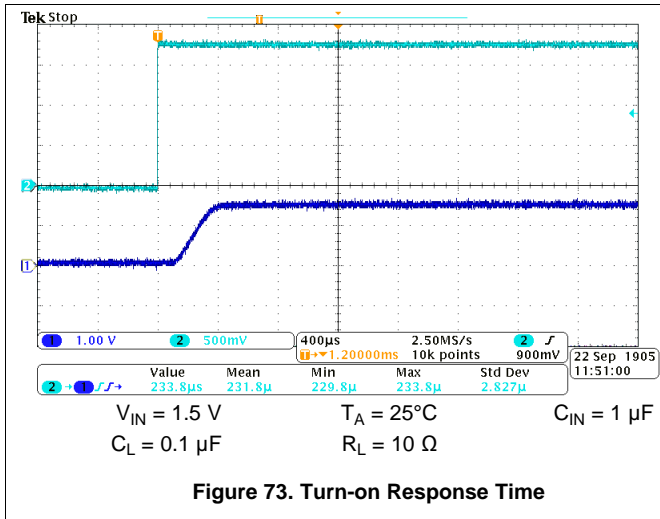


Figure 72. Turn-off Response Time



### 11.2.3.4 Typical Application Characteristics for TPS22913C

The dark blue curve (Channel 1) represents the VOUT pin of the device. The light blue curve (Channel 2) represents the ON pin of the device.

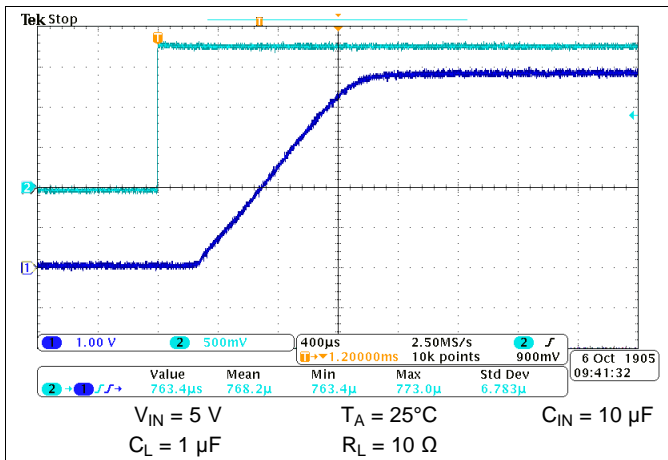


Figure 75. Turn-On Response Time

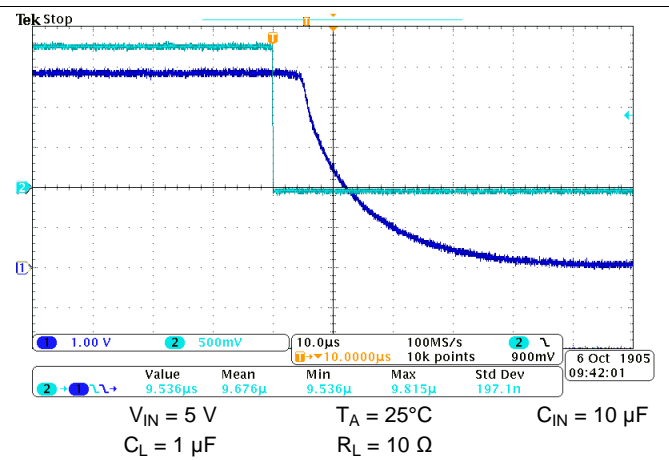


Figure 76. Turn-Off Response Time

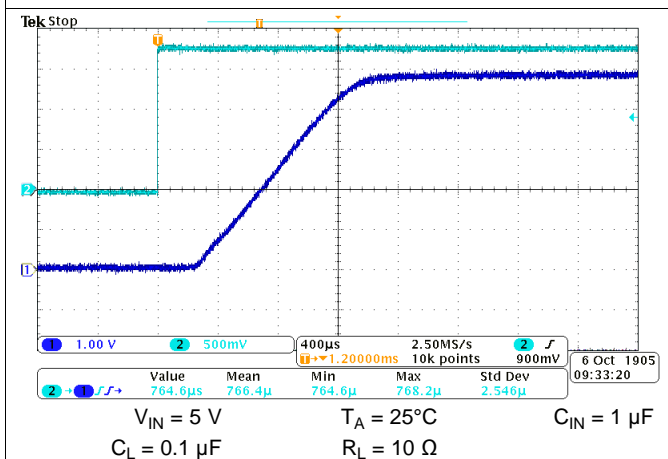


Figure 77. Turn-On Response Time

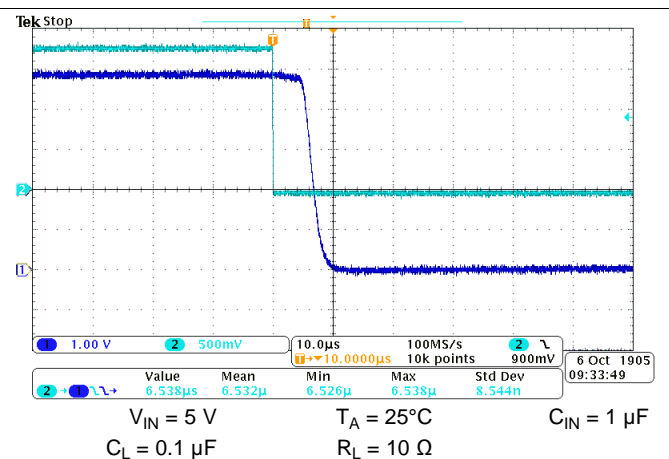


Figure 78. Turn-Off Response Time

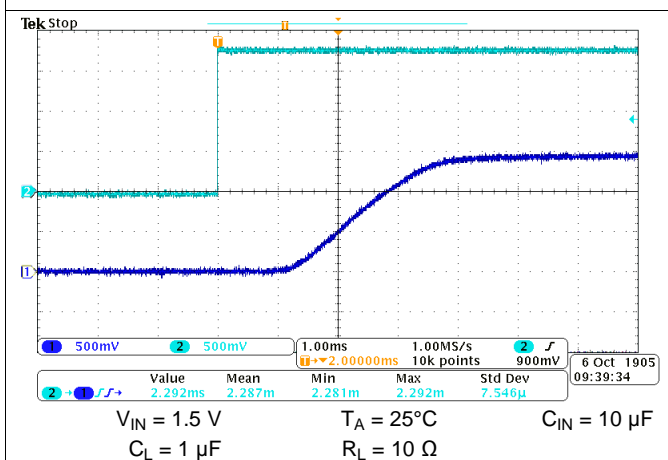


Figure 79. Turn-Off Response Time

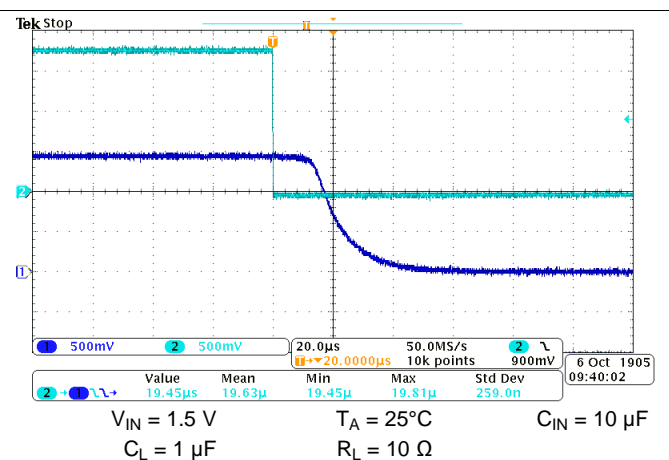
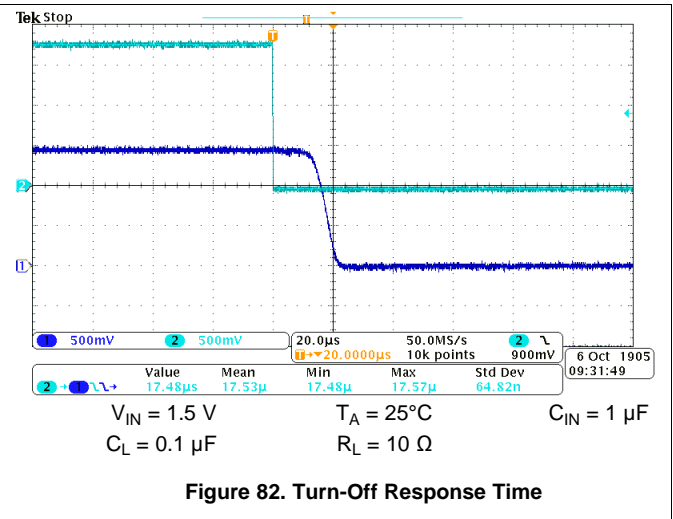
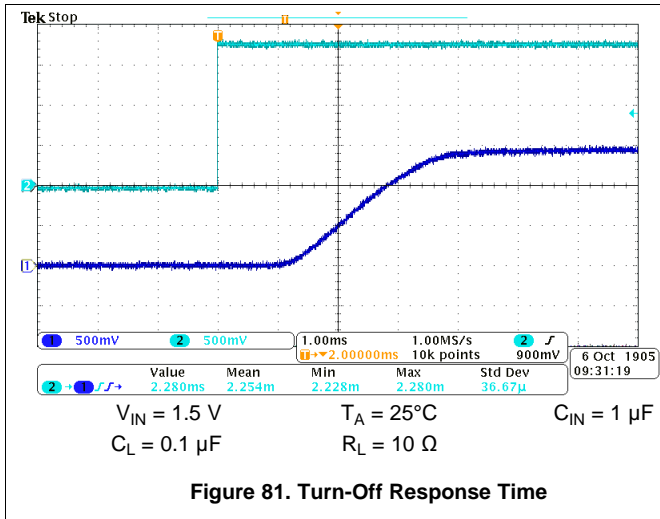


Figure 80. Turn-On Response Time



## 12 Power Supply Recommendations

The device is designed to operate with a  $V_{IN}$  range of 1.4 V to 5.5 V.

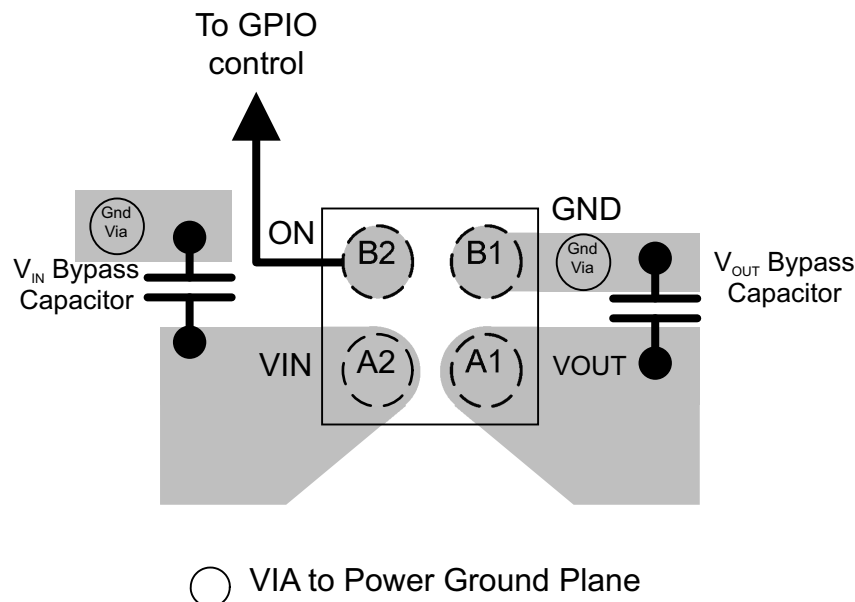
## 13 Layout

### 13.1 Layout Guidelines

For best performance, all traces should be as short as possible. To be most effective, the input and output capacitors should be placed close to the device to minimize the effects that parasitic trace inductances may have on normal operation. Using wide traces for  $V_{IN}$ ,  $V_{OUT}$ , and GND helps minimize the parasitic electrical effects along with minimizing the case to ambient thermal impedance.

### 13.2 Layout Example

The figure below shows an example for these devices. Notice the connection to system ground between the  $V_{OUT}$  Bypass Capacitor ground and the GND pin of the load switch, this creates a ground barrier which helps to reduce the ground noise seen by the device.



### 13.3 Thermal Considerations

The maximum IC junction temperature should be restricted to 125°C under normal operating conditions. To calculate the maximum allowable dissipation,  $P_{D(max)}$  for a given output current and ambient temperature, use the following equation as a guideline:

$$P_{D(max)} = \frac{T_{J(max)} - T_A}{R_{\theta JA}} \quad (5)$$

where

- $P_{D(max)}$  = maximum allowable power dissipation
- $T_{J(max)}$  = maximum allowable junction temperature
- $T_A$  = ambient temperature of the device
- $\theta_{JA}$  = junction to air thermal impedance. See the [Thermal Information](#) section. This parameter is highly dependent upon board layout.

## 14 Device and Documentation Support

### 14.1 Related Links

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

**Table 3. Related Links**

PARTS	PRODUCT FOLDER	SAMPLE & BUY	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY
TPS22910A	<a href="#">Click here</a>	<a href="#">Click here</a>	<a href="#">Click here</a>	<a href="#">Click here</a>	<a href="#">Click here</a>
TPS22912C	<a href="#">Click here</a>	<a href="#">Click here</a>	<a href="#">Click here</a>	<a href="#">Click here</a>	<a href="#">Click here</a>
TPS22913B	<a href="#">Click here</a>	<a href="#">Click here</a>	<a href="#">Click here</a>	<a href="#">Click here</a>	<a href="#">Click here</a>
TPS22913C	<a href="#">Click here</a>	<a href="#">Click here</a>	<a href="#">Click here</a>	<a href="#">Click here</a>	<a href="#">Click here</a>

### 14.2 Trademarks

Ultrabook is a trademark of Intel.

All other trademarks are the property of their respective owners.

### 14.3 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

### 14.4 Glossary

[SLYZ022](#) — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

## 15 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

**PACKAGING INFORMATION**

Orderable part number	Status (1)	Material type (2)	Package   Pins	Package qty   Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
<a href="#">TPS22910AYZVR</a>	Active	Production	DSBGA (YZV)   4	3000   LARGE T&R	Yes	SAC396	Level-1-260C-UNLIM	-40 to 85	75
<a href="#">TPS22910AYZVT</a>	Active	Production	DSBGA (YZV)   4	250   SMALL T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 85	75
<a href="#">TPS22912CYZVR</a>	Active	Production	DSBGA (YZV)   4	3000   LARGE T&R	Yes	SAC396	Level-1-260C-UNLIM	-40 to 85	78
<a href="#">TPS22912CYZVT</a>	Active	Production	DSBGA (YZV)   4	250   SMALL T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 85	78
<a href="#">TPS22913BYZVR</a>	Active	Production	DSBGA (YZV)   4	3000   LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 85	64
<a href="#">TPS22913BYZVT</a>	Active	Production	DSBGA (YZV)   4	250   SMALL T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 85	64
<a href="#">TPS22913CYZVR</a>	Active	Production	DSBGA (YZV)   4	3000   LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 85	76
<a href="#">TPS22913CYZVT</a>	Active	Production	DSBGA (YZV)   4	250   SMALL T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 85	76

<sup>(1)</sup> **Status:** For more details on status, see our [product life cycle](#).

<sup>(2)</sup> **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

<sup>(3)</sup> **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

<sup>(4)</sup> **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

<sup>(5)</sup> **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

<sup>(6)</sup> **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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**TAPE AND REEL INFORMATION**

**QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE**


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS22910AYZVR	DSBGA	YZV	4	3000	178.0	9.2	1.0	1.0	0.63	4.0	8.0	Q1
TPS22910AYZVT	DSBGA	YZV	4	250	178.0	9.2	1.0	1.0	0.63	4.0	8.0	Q1
TPS22912CYZVR	DSBGA	YZV	4	3000	178.0	9.2	1.0	1.0	0.63	4.0	8.0	Q1
TPS22912CYZVT	DSBGA	YZV	4	250	178.0	9.2	1.0	1.0	0.63	4.0	8.0	Q1
TPS22913BYZVR	DSBGA	YZV	4	3000	180.0	8.4	1.0	1.0	0.63	4.0	8.0	Q1
TPS22913BYZVT	DSBGA	YZV	4	250	180.0	8.4	1.0	1.0	0.63	4.0	8.0	Q1
TPS22913CYZVR	DSBGA	YZV	4	3000	180.0	8.4	1.0	1.0	0.63	4.0	8.0	Q1
TPS22913CYZVT	DSBGA	YZV	4	250	180.0	8.4	1.0	1.0	0.63	4.0	8.0	Q1

**TAPE AND REEL BOX DIMENSIONS**


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS22910AYZVR	DSBGA	YZV	4	3000	220.0	220.0	35.0
TPS22910AYZVT	DSBGA	YZV	4	250	220.0	220.0	35.0
TPS22912CZVR	DSBGA	YZV	4	3000	220.0	220.0	35.0
TPS22912CZVT	DSBGA	YZV	4	250	220.0	220.0	35.0
TPS22913BZVR	DSBGA	YZV	4	3000	182.0	182.0	20.0
TPS22913BZVT	DSBGA	YZV	4	250	182.0	182.0	20.0
TPS22913CZVR	DSBGA	YZV	4	3000	182.0	182.0	20.0
TPS22913CZVT	DSBGA	YZV	4	250	182.0	182.0	20.0

YZV (S-XBGA-N4)

DIE-SIZE BALL GRID ARRAY



4206083/C 07/13

- NOTES:
- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
  - B. This drawing is subject to change without notice.
  - C. NanoFree™ package configuration.

NanoFree is a trademark of Texas Instruments.

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